Nonlinear Nanophotonics I

Alexander Gaeta

Department of Applied Physics and Applied Mathematics

Columbia University

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University of Campinas, July 25-29, 2016

Nonlinear Optical Interactions over 23-Orders of Magnitude

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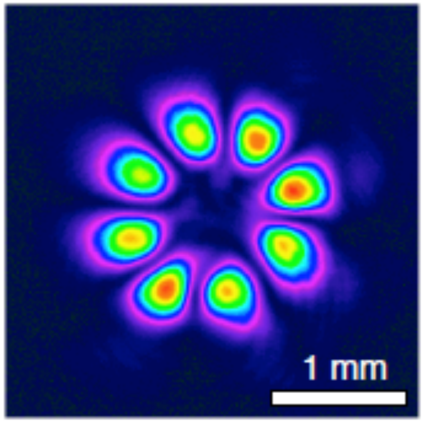
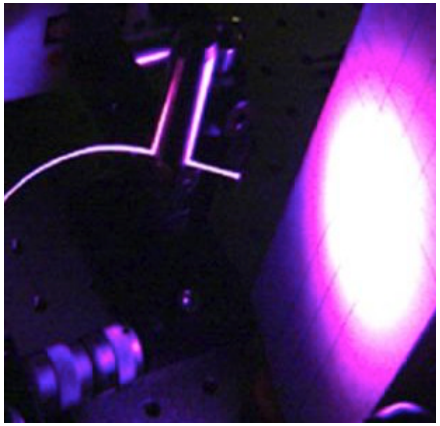
Intense-Field Physics



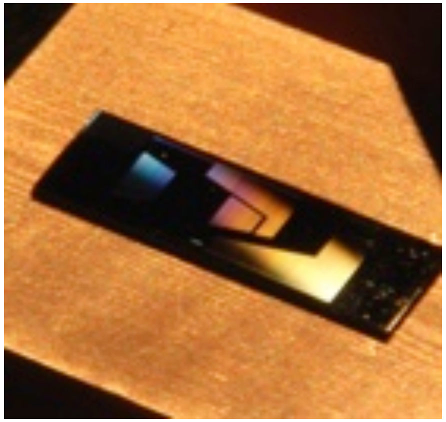
10 MW – 1 TW

Fiber-Based NLO



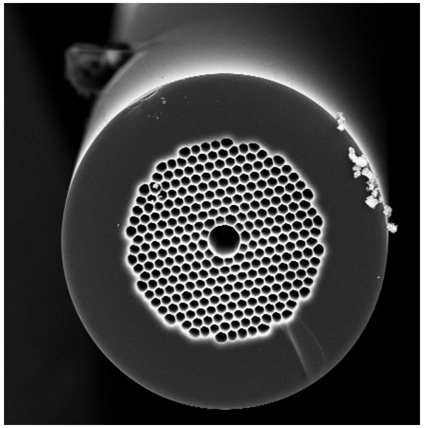
1 W – 100 kW

Chip-Based Nanophotonics



100 μW – 100 mW

Ultralow-Power Atom Interactions



10 pW – 1 μW

Outline: Nonlinear Nanophotonics I

Lecture I

- Brief review of linear & nonlinear optics waveguides
- Nonlinear processes in nanowaveguides
- Four-wave mixing (FWM) in Si nanowaveguides
  - Dispersion engineering
  - Ultra-broadband wavelength conversion
  - Applications: correlated photons, signal regeneration

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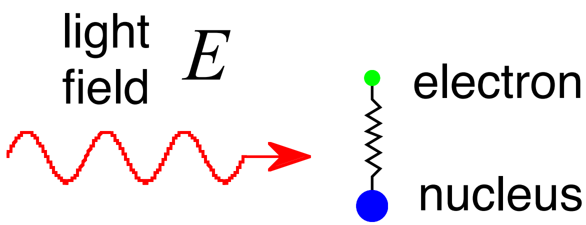
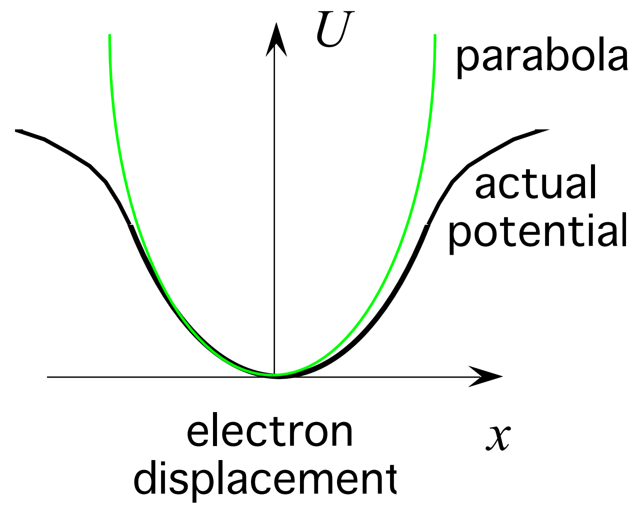
- Microscopic picture: Lorentz-atom model.



restoring force: $F_{res} = -kx + ax^2 + bx^3 + \ldots$



- Macroscopic picture: nonlinear dependence on applied field.

polarization of the medium

$$P = \chi^{(1)}E + \cancel{\chi^{(2)}}E^2 + \chi^{(3)}E^3 + \ldots$$

linear susceptibility

nonlinear susceptibilities

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2nd-Order Nonlinear Processes

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- Consider oscillating electric field: $E(t) = A\cos\omega t$

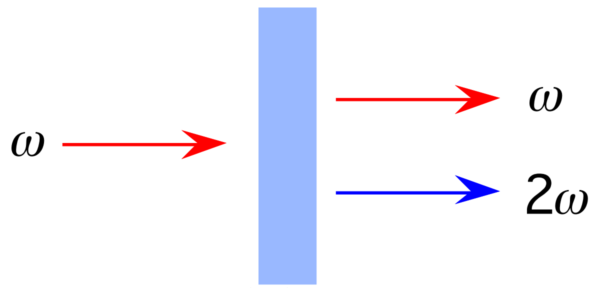
- $\chi^{(2)}$ effects: second-harmonic generation:

$$P^{(2)}(t) = \chi^{(2)}E^2(t) = \chi^{(2)}\frac{A^2}{2}(1 + \cos 2\omega t)$$

dc

second-harmonic

frequency doubling



$\chi^{(2)}$ material

- Other processes:
  - terahertz generation
  - sum- and difference-frequency generation
  - optical parametric amplification

- Only occurs in non-centrosymmetric crystals.
  - requires phase-matching (e.g., $n_\omega = n_{2\omega}$)

3rd-Order Nonlinear Processes

- $\chi^{(3)}$ effects: intensity-dependent refractive index

$$P^{(3)}(t) = \chi^{(3)} E^3(t) = \chi^{(3)} \frac{A^3}{4} (3\cos\omega t + \cos 3\omega t)$$

intensity-dependent refractive index

3rd-harmonic (usually not phase matched)

<u>All materials exhibit a nonlinear refractive index (usually *n*$_2$ > 0)</u>

L

A_{in} $\xrightarrow{\omega}$ $\xrightarrow{\omega}$ $A_{out} = A_{in} e^{i\phi_{nl}}$

$$n_2 \propto \mathrm{Re}\left\{\chi^{(3)}\right\}$$

$$n = n_0 + n_2 I$$

intensity

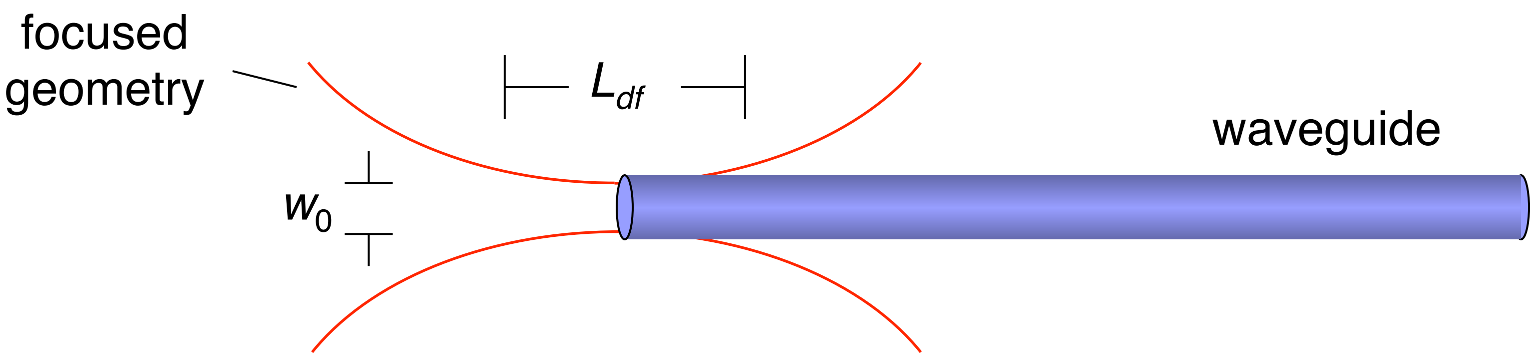
$$n_2^{glass} \sim 10^{-16}\ \mathrm{cm}^2/\mathrm{W}$$

$$n_2^{Si} \sim 10^{-14}\ \mathrm{cm}^2/\mathrm{W}$$

$$n_2^{air} \sim 10^{-20}\ \mathrm{cm}^2/\mathrm{W}$$

- Nonlinear phase shift is important when: $\phi_{nl} = \dfrac{2\pi}{\lambda} n_2 I L \geq \pi$

Nonlinear Interactions: Why Waveguides?



power

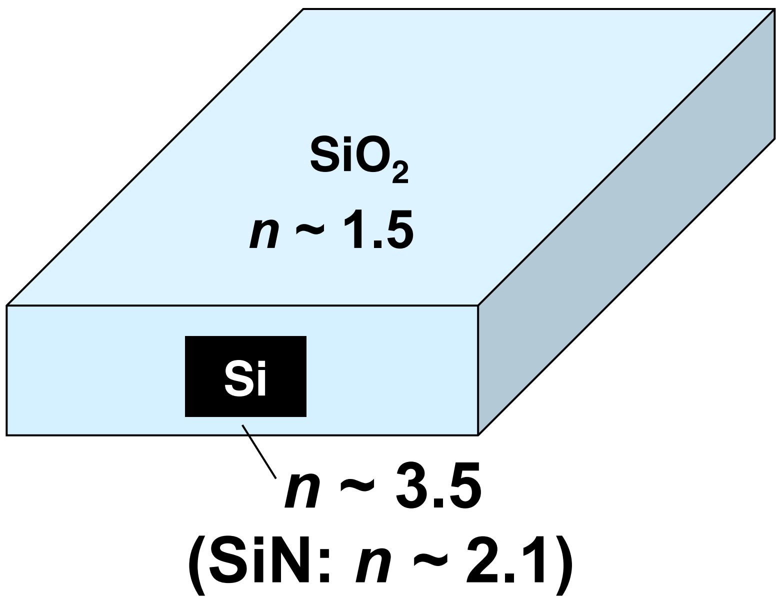
nonlinear parameter $$\phi_{NL} = \kappa_{NL} \frac{P}{w_0^2} L$$

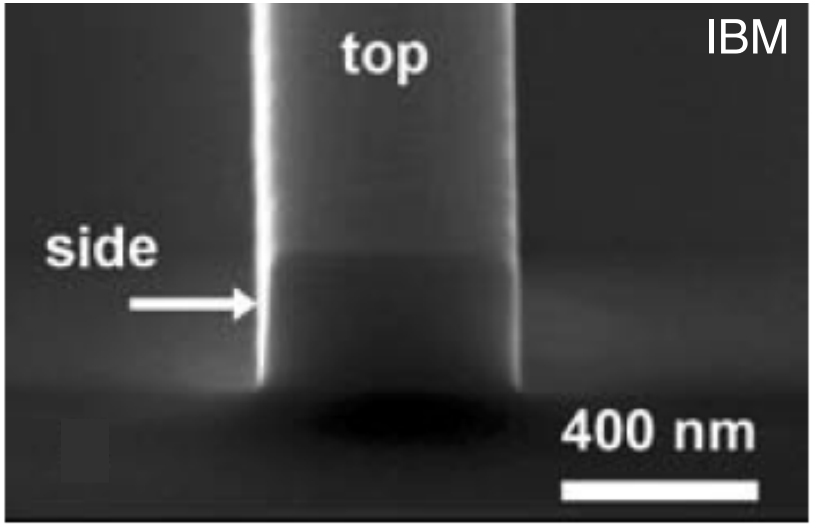
area

interaction length

- **Interaction length can be >> the diffraction length.**
- **Dispersion can be engineered.**

Nonlinear Optics in Silicon-Based Nanowaveguides





Absorption edge: Silicon => ~ 1.1 μm Si_3N_4 => ~ 400 nm

- Nonlinearity of Silicon 100X (Si_3N_4: 10X) silica
- Losses: Silicon – 1 dB/cm (Si_3N_4 – 0.01 dB/cm)
- Light confined to a region < than a wavelength.

Nonlinear Optics in Silicon-Based Nanowaveguides

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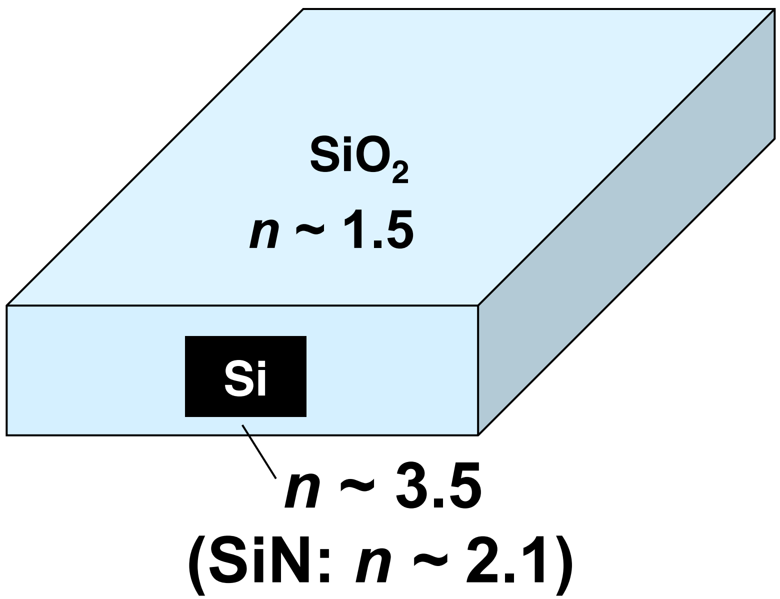

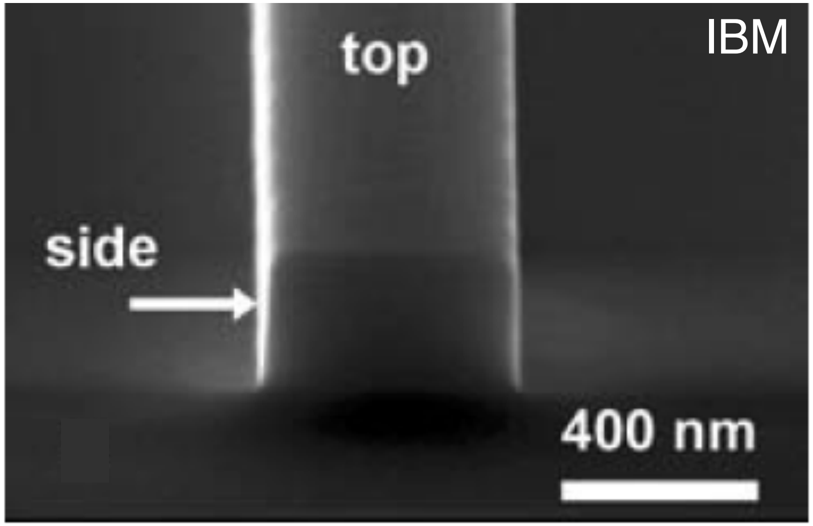

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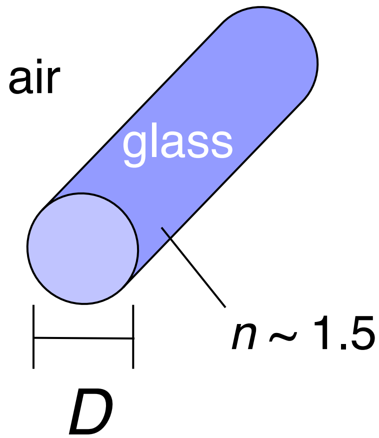
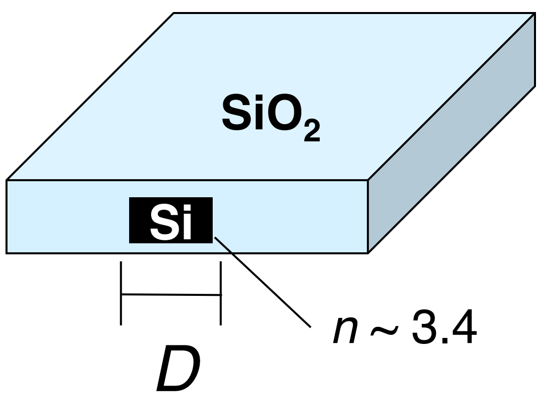
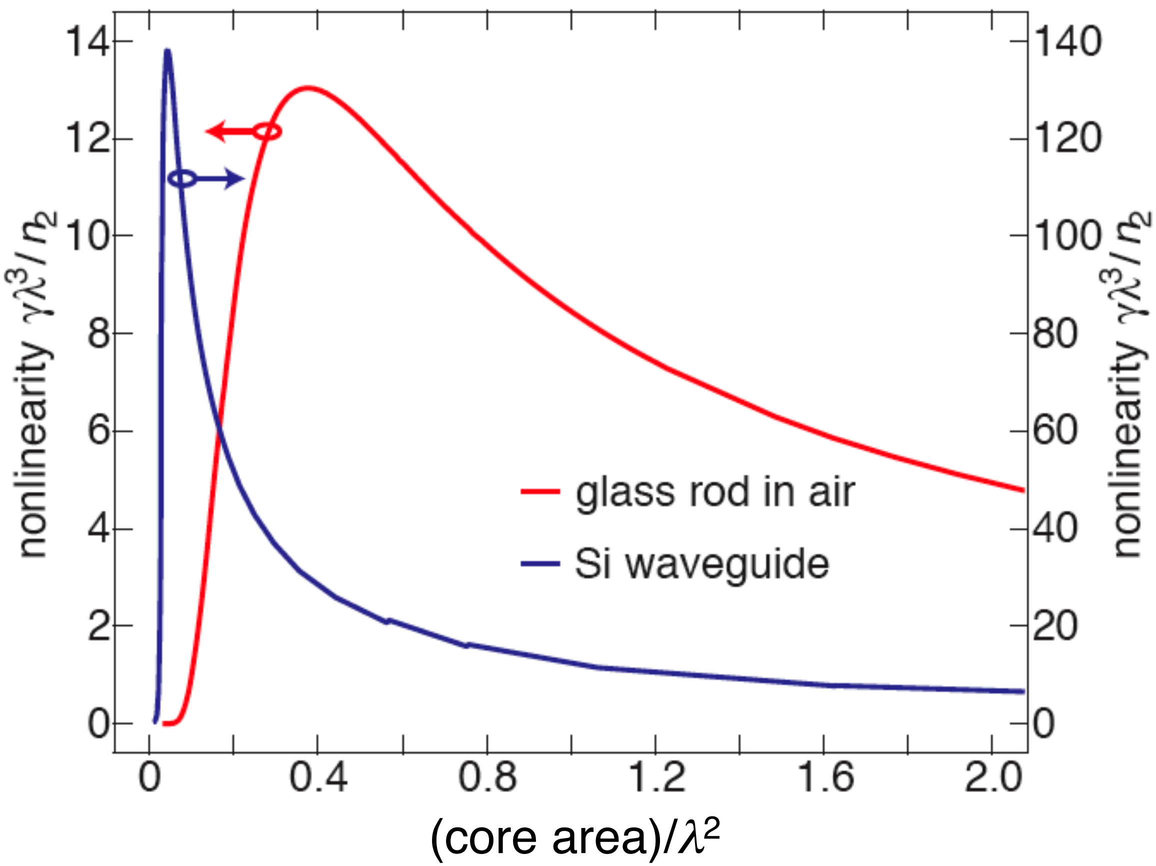
Confinement Properties of Ultra-Small-Core Waveguides





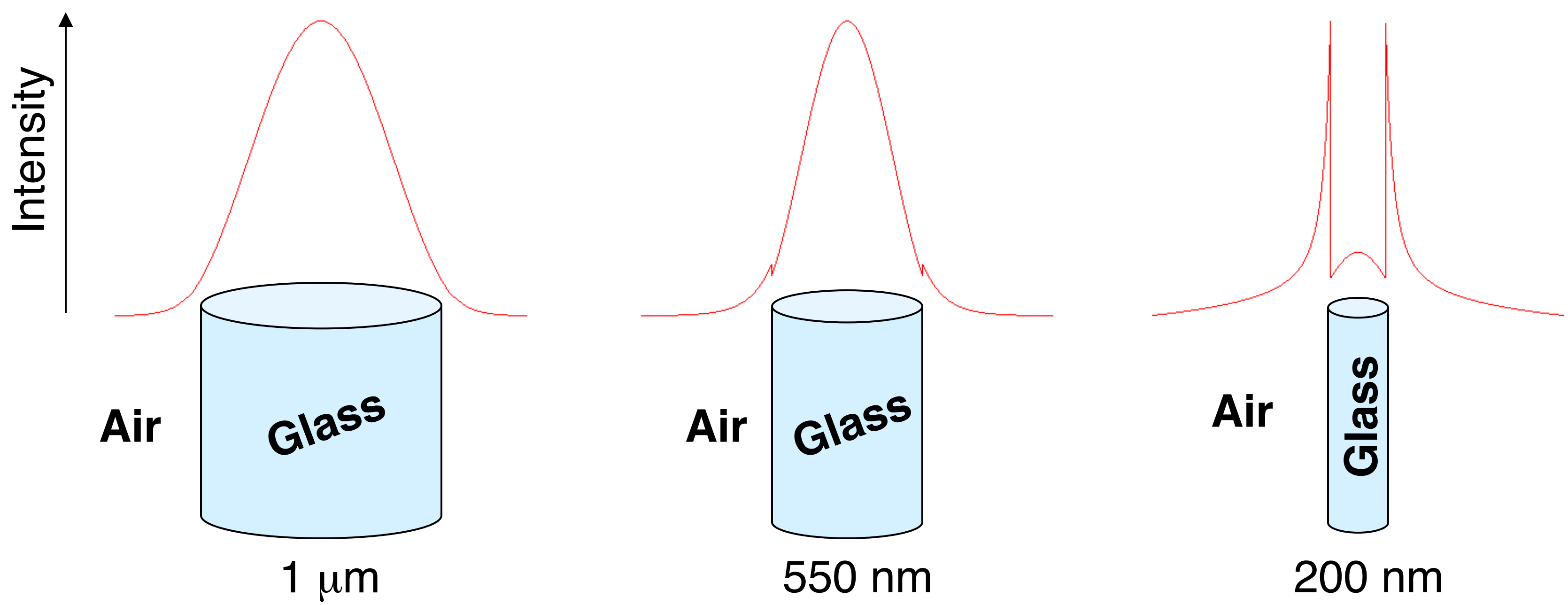


$$D_{optimal} < \lambda$$

Foster, Moll, and Gaeta, *Opt. Express* **12**, 2880 (2004)

Confinement Properties

λ = 800 nm



Dispersion

- Expand propagation constant in power series expansion

$$k(\omega) = \frac{n(\omega)\omega}{c} = k_0 + k_1(\omega-\omega_0) + \frac{1}{2}k_2(\omega-\omega_0)^2 + \ldots \qquad k_m = \left.\frac{d^m k}{d\omega^m}\right|_{\omega=\omega_0}$$

propagation constant

$$k_0 = \frac{n_{mode}(\omega_0)\,\omega_0}{c}$$

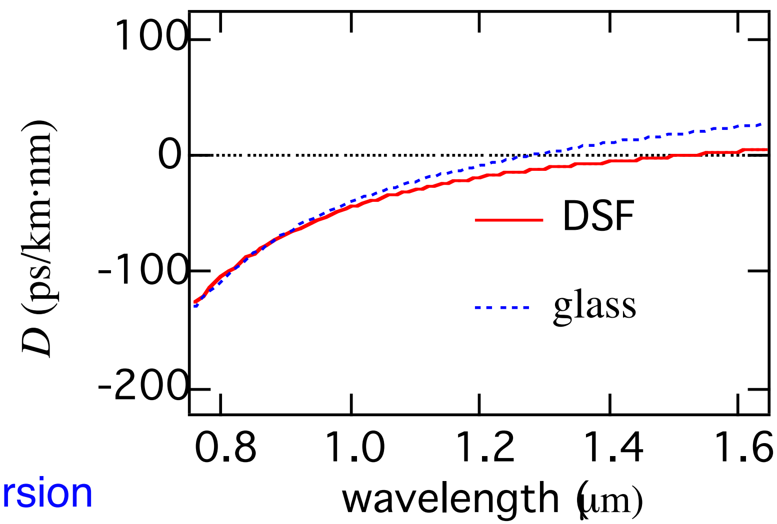
inverse of group velocity

$$k_1 = \left.\frac{dk}{d\omega}\right|_{\omega=\omega_0} = \frac{1}{v_{gr}}$$

group-velocity dispersion

$$k_2 = \left.\frac{d^2k}{d\omega^2}\right|_{\omega=\omega_0} = -\frac{\lambda^2}{2\pi c}D$$

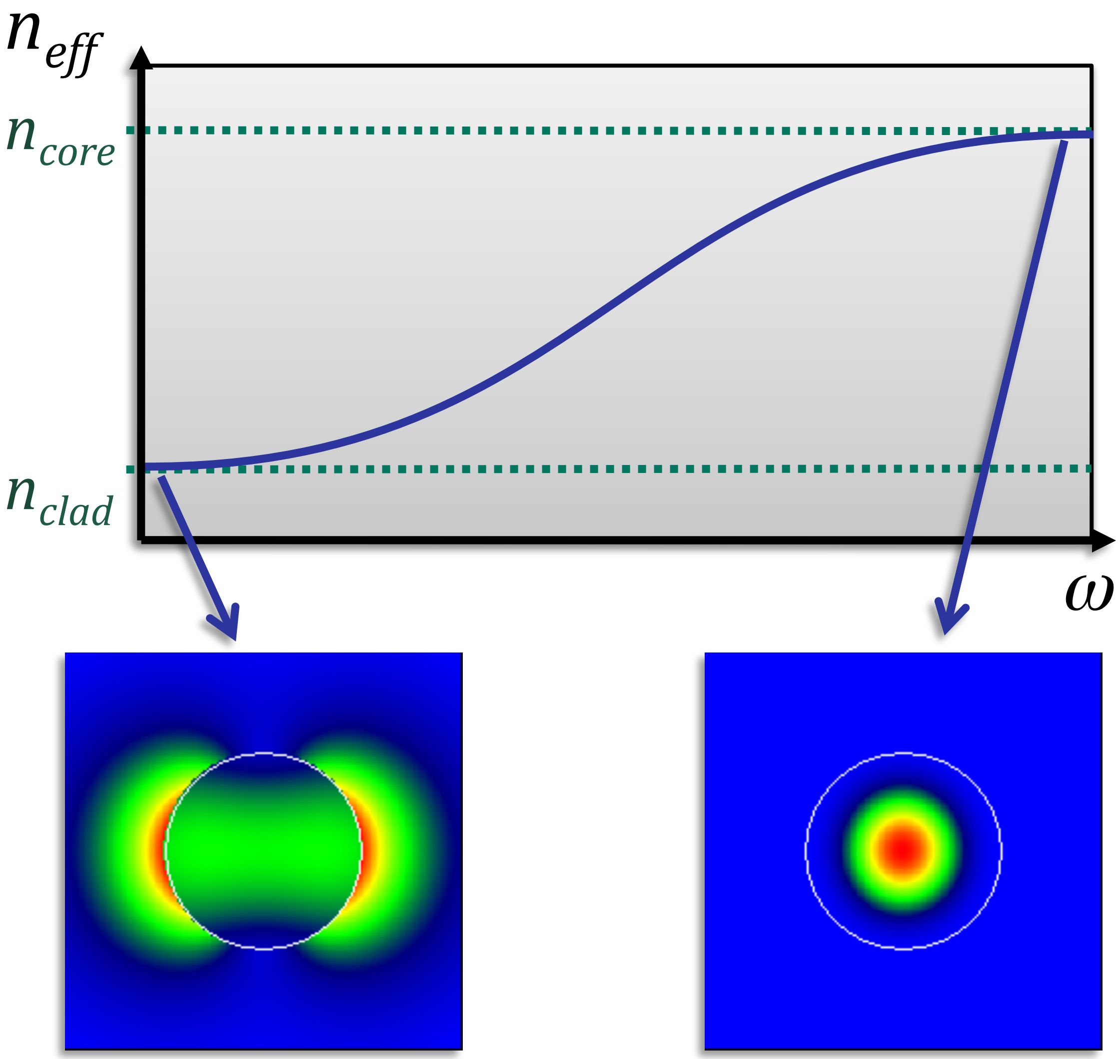
dispersion parameter



$D > 0$ anomalous dispersion

$D < 0$ normal dispersion

Waveguide Dispersion



Mode effective index

- Short λ, high ω
  - Mode is fully confined
  - $n_{eff} \rightarrow n_{core}$
- Long λ, low ω
  - Mode expands outside core
  - $n_{eff} \rightarrow n_{clad}$
- Step-index core
  - Smooth transition

Nonlinear Propagation in Waveguides: Nonlinear Schrödinger Equation

[*Nonlinear Optics*, Boyd (2009)]

$$\frac{\partial u}{\partial z} = -\operatorname{sgn}(k_2)\frac{i}{2}\frac{\partial^2 u}{\partial \tau^2} + i\frac{L_{ds}}{L_{nl}}|u|^2 u$$

dispersion   nonlinearity

$z = z/L_{ds}$

$\tau = \dfrac{t - z/v_{gr}}{\tau_p}$

local time

input pulse duration

$u = \dfrac{A}{A_0}$

input amplitude

dispersion length $L_{ds} = \dfrac{\tau_p^2}{|k_2|}$

nonlinear length $L_{nl} = \dfrac{cA_{eff}}{\omega_0 n_2 P_0}$

efffective mode area

$P_0 \propto |A_0|^2$ input power

- Describes very well propagation of pulses in waveguides.
- Additional nonlinearities (e.g., Raman scattering) can be easily included.
- Addition of self-steepening allows for treatment of ~ single-cycle pulses.

NLO in Silicon-Based Waveguides

- Raman scattering
  - Raman gain & oscillation [Claps et al 2003; Rong et al 2004; Espinola et al 2004; Xu, et al. 2005; Rong et al 2004; Boyraz et al 2004]
  - Raman-induced slow light [Okawachi et al 2006]
  - Zeno-switching [Wen et al 2011]
- Instantaneous Kerr nonlinearity
  - phase modulation & continuum generation [Tsang et al 2002; Boyraz et al 2004; Dulkeith et al, 2006; Hsieh et al, 2006; Hsieh, et al 2007; Koonath, et al 2007; Kuyken, et al. 2011; Halir, et al 2012]
  - harmonic generation [Corcoran et al. 2009; Levy et al. 2011]
- Four-wave mixing [Dimitropoulos et al 2004; Fukuda et al 2005; Espinola et al 2005; Yamada et al 2006; Rong et al 2006; Foster et al. 2006; Koos et al 2009); McMillan et al 2010; Zlatanovic et al. 2010; Xiaoping et al. 2010; Kuyken et al. 2011; Hu, et al. 2011]
  - generation of correlated photons [Sharping, et al. 2006; Harada et al 2007; Clemmen et al 2008]
  - signal regeneration [Salem, et al 2007, 2008]
  - parametric oscillation & comb generation (Levy, et al 2010; Foster et al 2011; Okawachi et al 2011; Ferdous et al. 2011); Herr, et al 2012]
  - ultrafast processing [Foster, et al 2008; Salem et al 2008; Corcoran et al 2010; Christian, et al. 2011]

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Reviews: Foster, et al. *Opt. Express* **16**, 1300 (2008)

Osgood, et al., *Adv. Opt. Phot.* **1**, 162 (2009)

Leuthold, et al., *Nat. Phot.* **4** 535 (2010).

✧ ultrafast processing [Foster, et al 2008; Salem et al 2008; Corcoran et al 2010; Christian, et al. (2011)

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Self- and Cross-Phase Modulation

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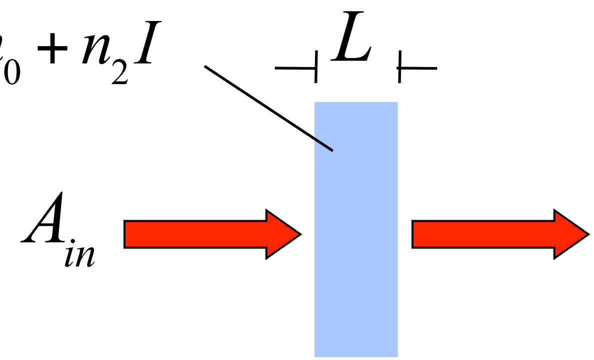
- Self-phase modulation (SPM)

$$n = n_0 + n_2 I$$

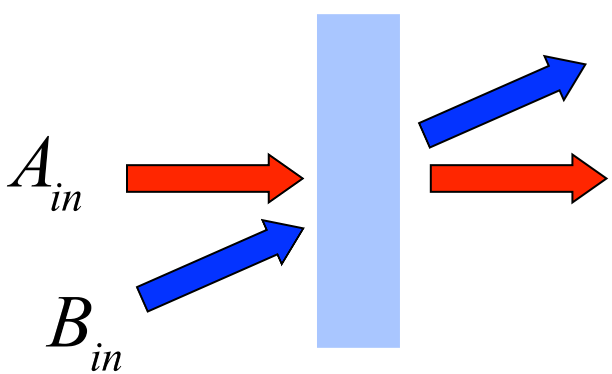


$$A_{out} = A_{in} e^{i\phi_{nl}}$$

SPM

$$\boxed{\phi_{nl} = \gamma I L}$$

- Cross-phase modulation (XPM)



$$A_{out} = A_{in} e^{i\phi_{nl}}$$

XPM

$$\boxed{\phi_{nl} = \gamma (I_A + 2 I_B) L}$$

Self-Phase Modulation w/ Pulses

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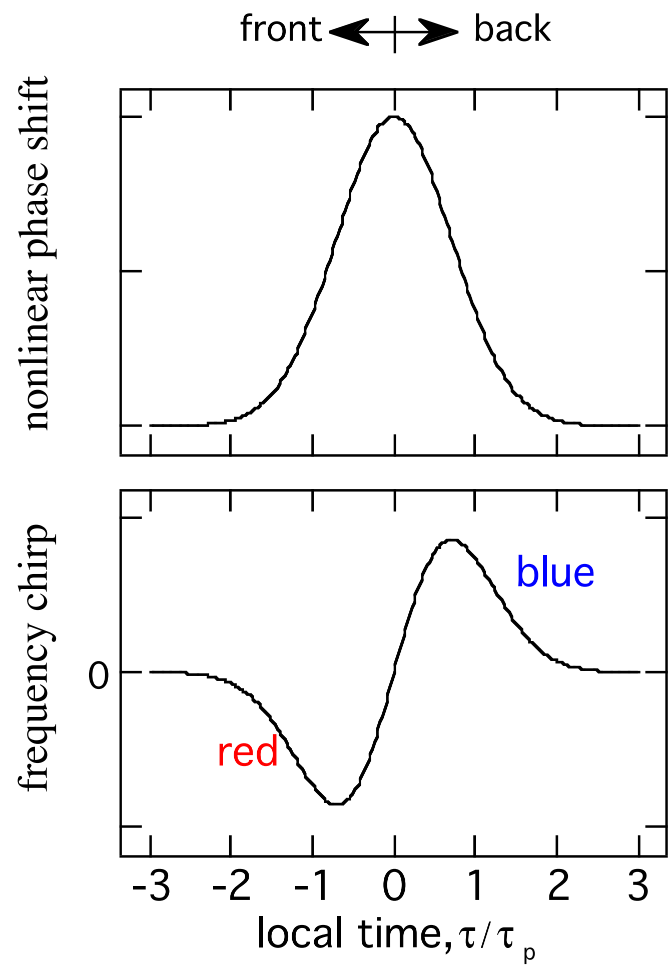
- Neglect dispersion:

output field $$A_{out}(\tau) = A_{in}(\tau)e^{i\phi_{nl}(\tau)}$$

nonlinear phase shift $$\phi_{nl}(\tau) = \frac{2\pi}{\lambda} n_2 I_{in}(\tau) L$$

frequency chirp $$\delta\omega(\tau) = -\frac{\partial\phi_{nl}}{\partial\tau} \propto \frac{\phi_{nl}^{\max}}{\tau_p}$$

- Pulse duration is unchanged, but spectrum is broadened.



Spectral Broadening via SPM

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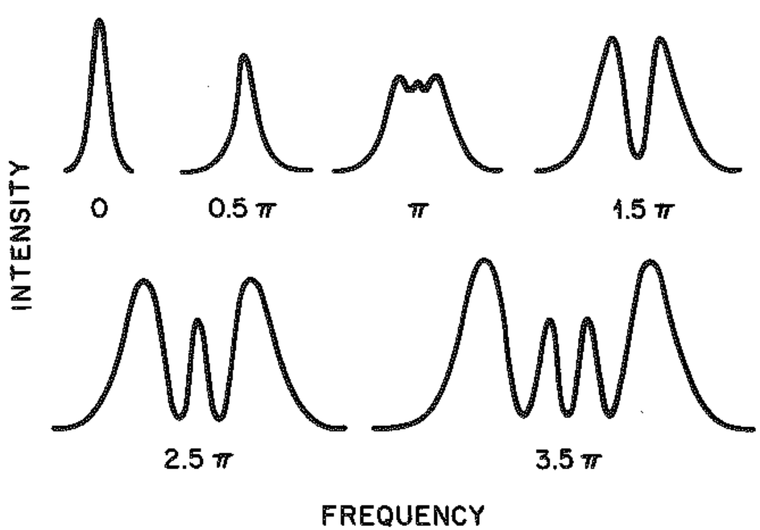
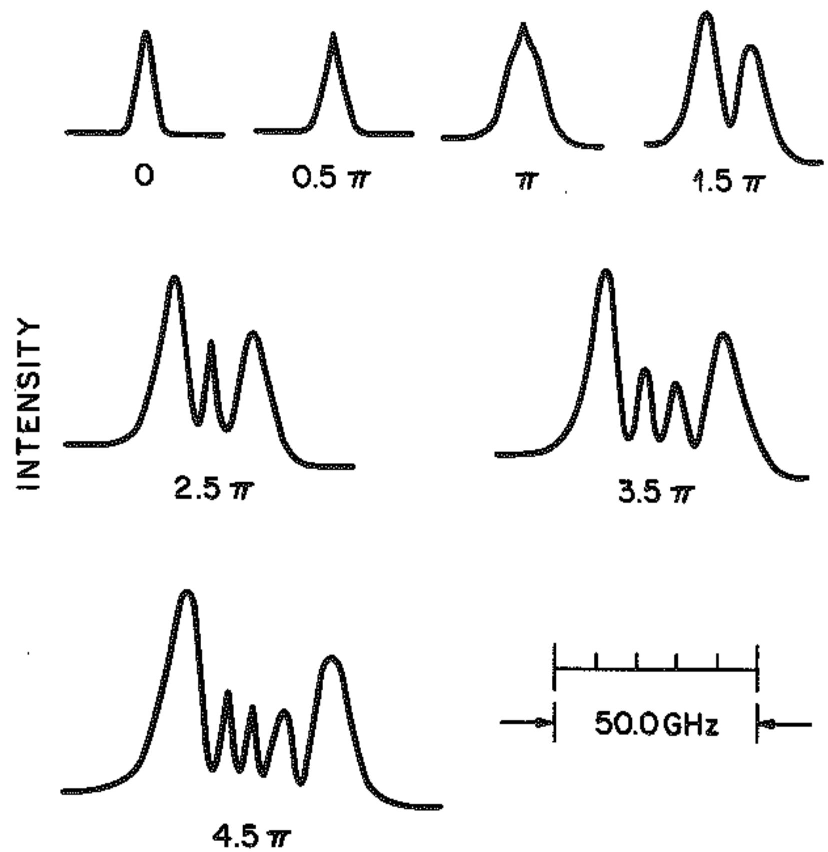
Theory



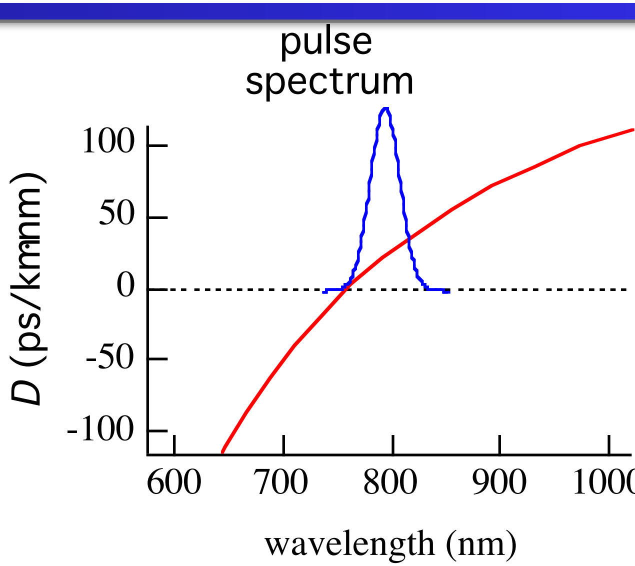
Experiment

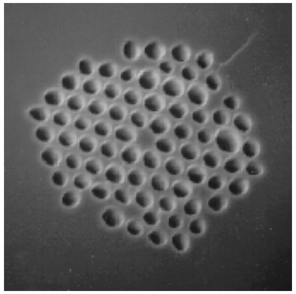


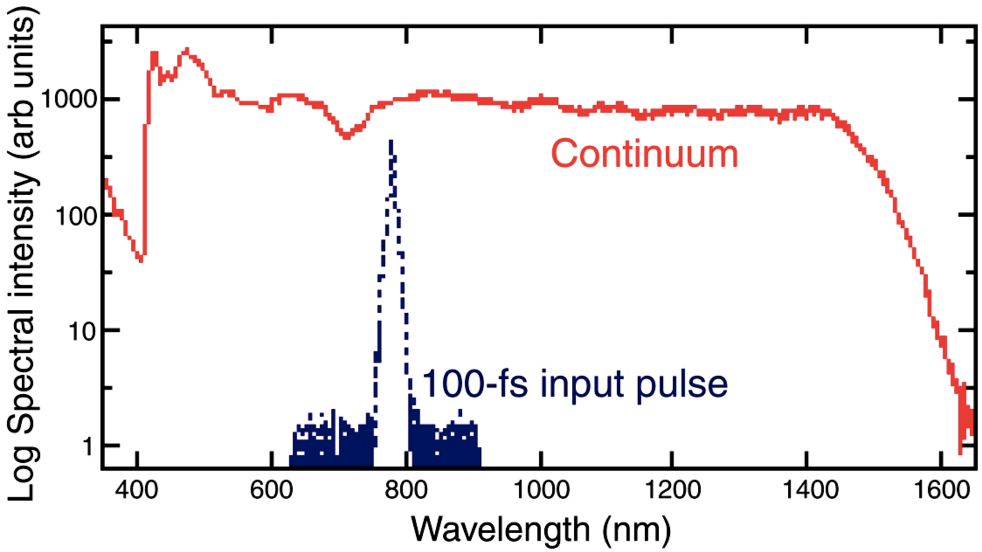
Stolen and Lin, Phys. Rev. A **17**, 1448 (1978).

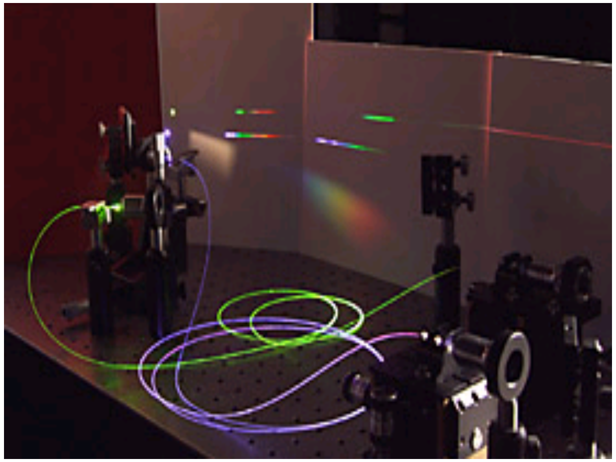
Supercontinuum Generation in Optical Waveguides

- Initial observation: Inject < 100 fs pulses directly from Ti:sapphire modelocked oscillator.
- Combination of small core and zero group-velocity dispersion allow for broad supercontinuum spanning > octave.



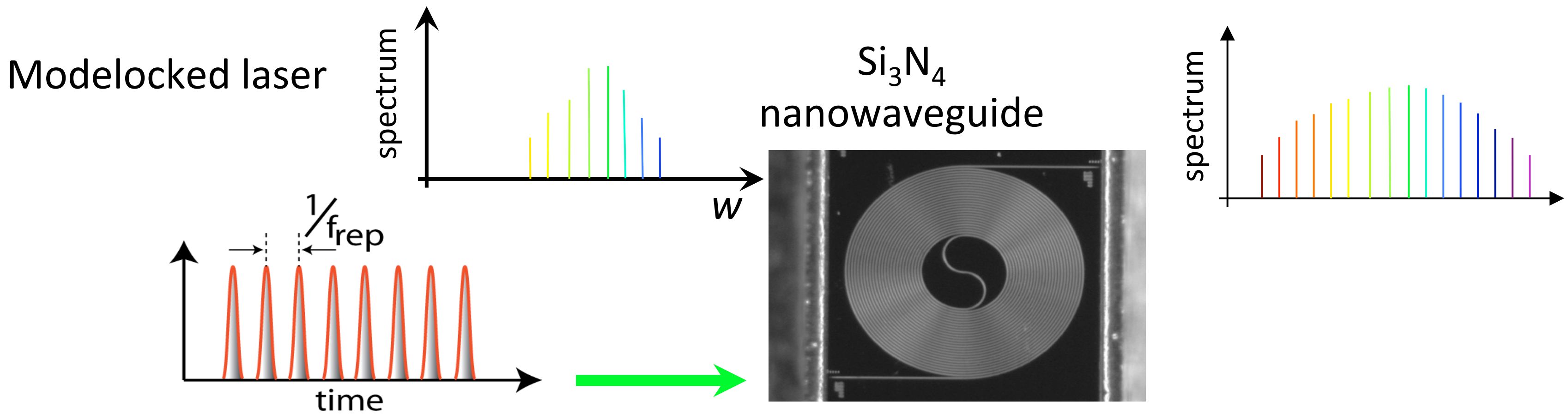






Ranka et al. 2001

Chip-Based Frequency Comb Generation in Si_3N_4 Waveguides



- Origin of combs can be traced to four-wave mixing (FWM)
- Requires small anomalous group-velocity dispersion

Halir, et al. Lipson & Gaeta, *Opt. Lett.* (2013).

Chavez-Boggio, et al., Bohm, JOSA B (2014).

Zhao, et al. Roelkens & Baets, *Opt. Lett.* (2015).

Epping, et al. Boller, *Opt. Lett.* (2015).

Mayer, et al. Lipson, Gaeta, & Keller, *Opt. Express* (2015).

Johnson, et al. Wise, Keller, Lipson, & Gaeta, *Opt. Lett.* (2015).

Klenner, et al. Lipson, Gaeta, & Keller, *Opt. Express* (2016)

Tailoring of GVD in Si-Based Waveguides

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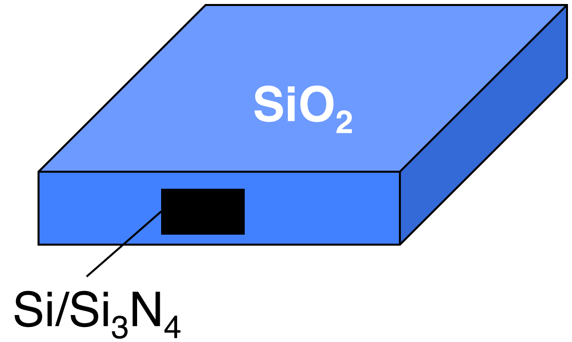
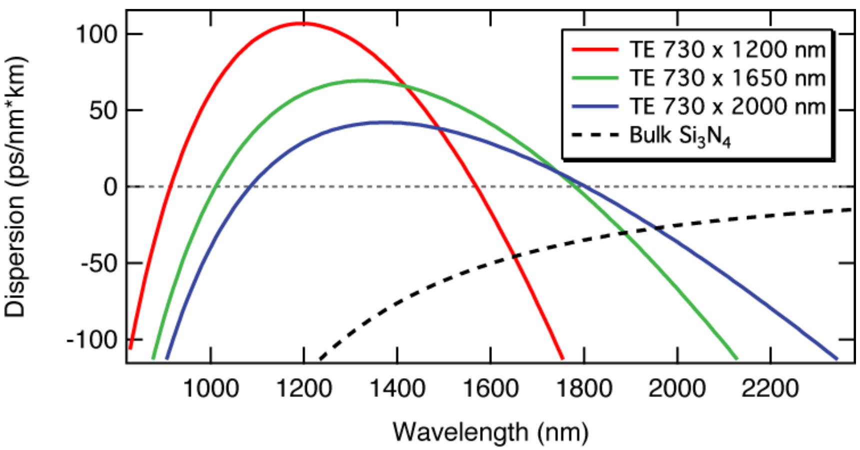
- GVD can be tuned by varying waveguide shape and size.
- Same chip can operate w/ different pump wavelengths.



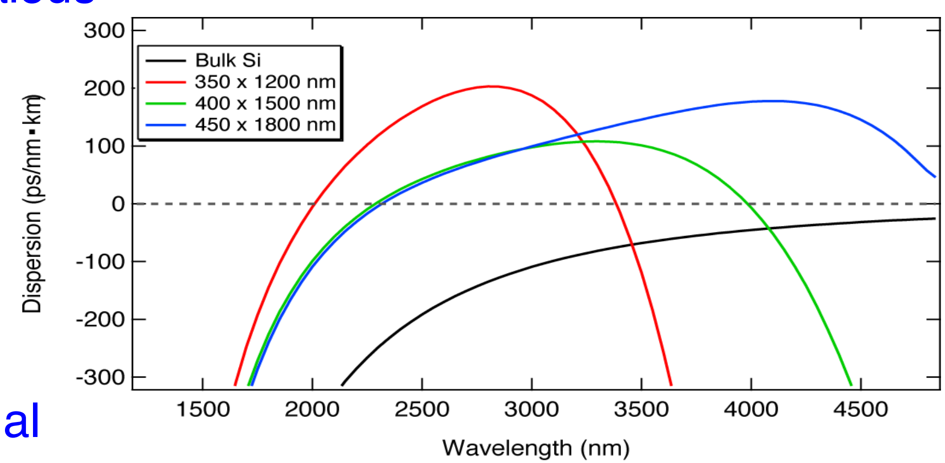
Si_3N_4



anomalous

normal

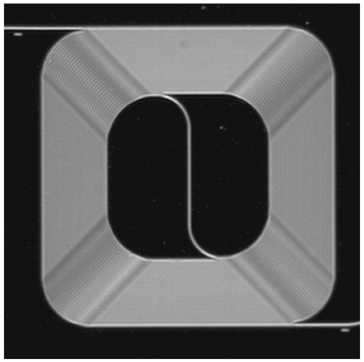
Si

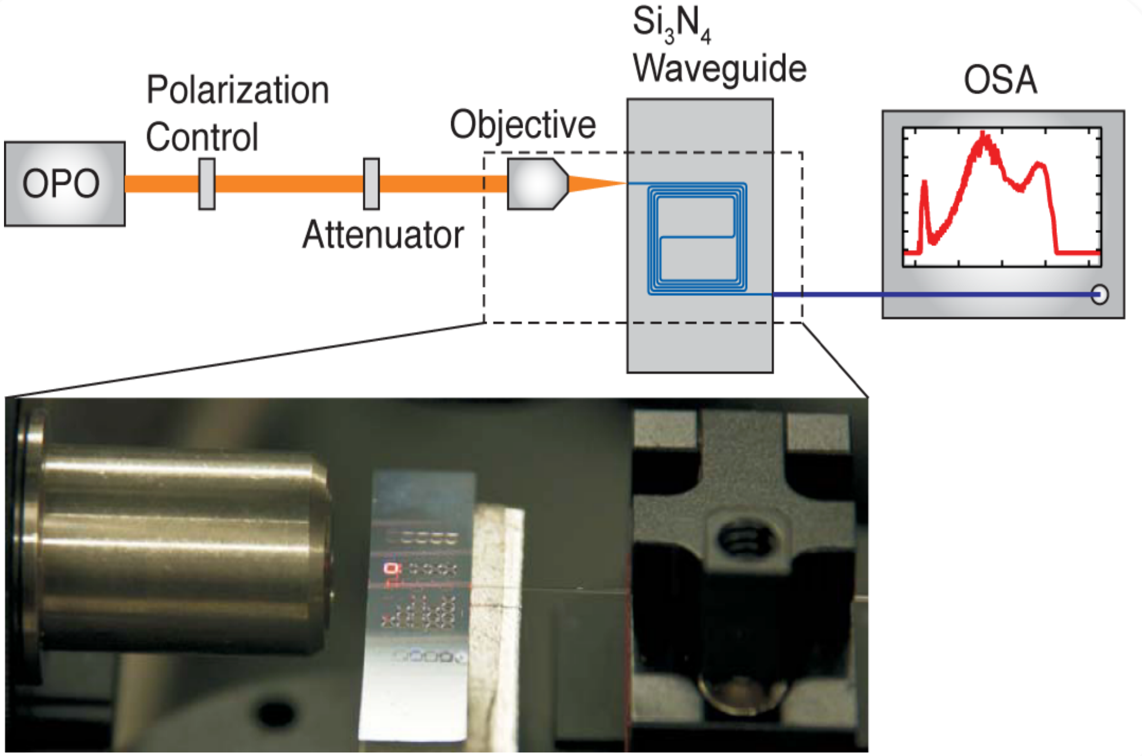


Foster, Turner, Sharping, Schmidt, Lipson, and Gaeta, *Nature* **441**, 960 (2006).
Turner, et al. Gaeta, and Lipson, *Opt. Express* **14**, 4357 (2006).

Experimental Setup for Supercontinuum Generation

- Si_3N_4 spiral waveguide with 4.3 cm length, 715 x 1100 nm cross section
- 0.8 dB/cm propagation loss
- 80-MHz repetition rate, 200-fs pulsewidth OPO centered at 1335 nm
- Quasi-TE polarization





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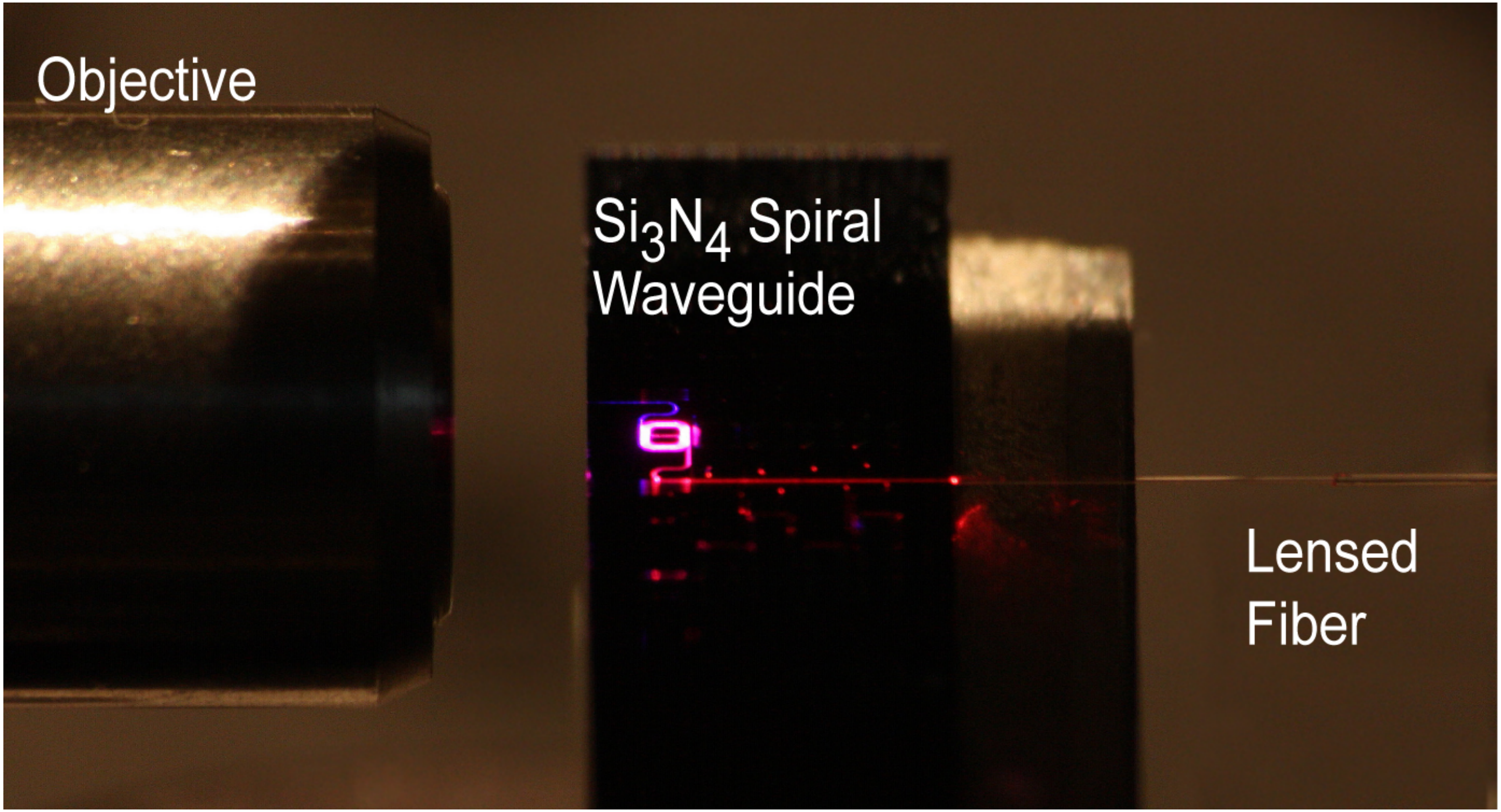
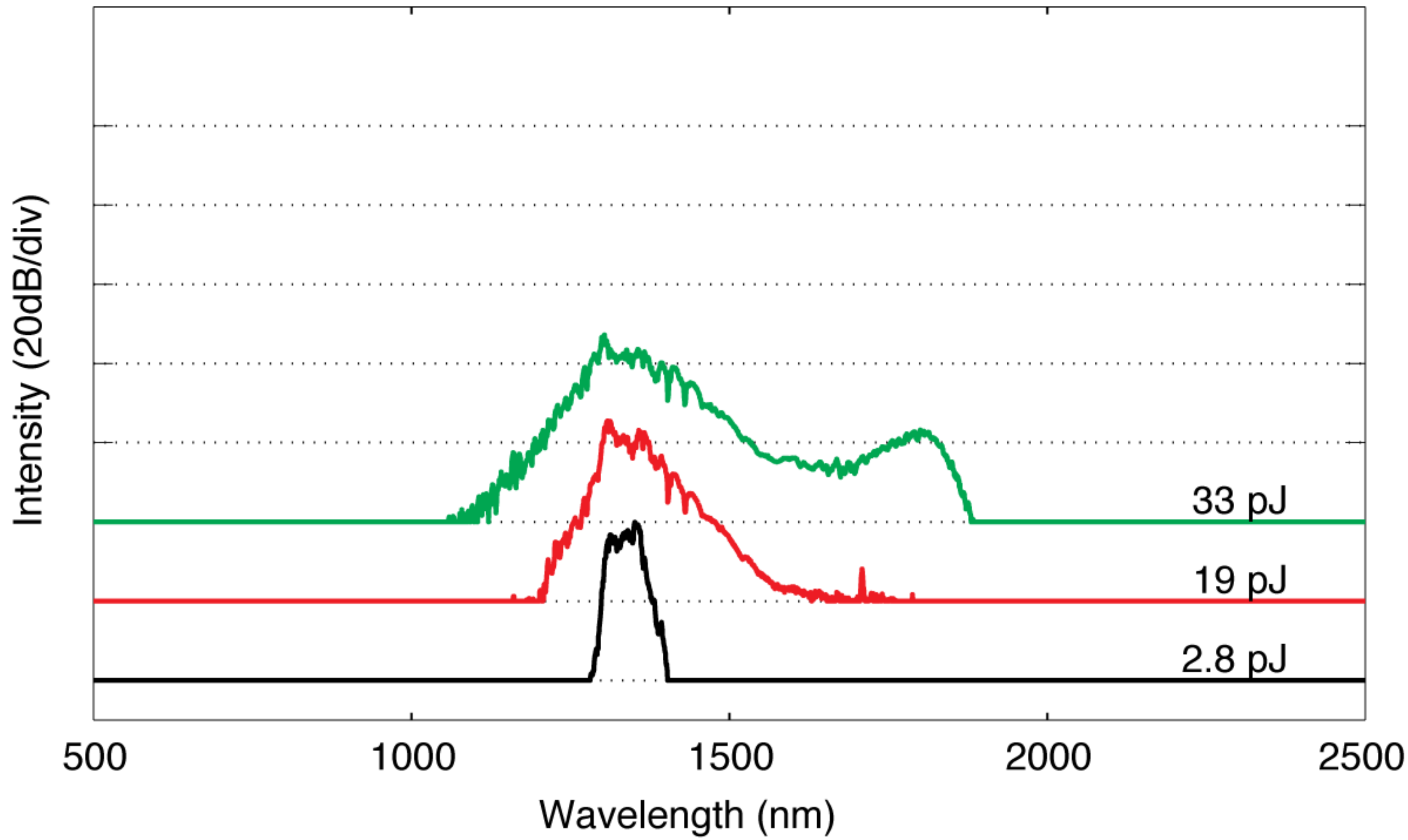


Supercontinuum Generation in Si_3N_4 Waveguide

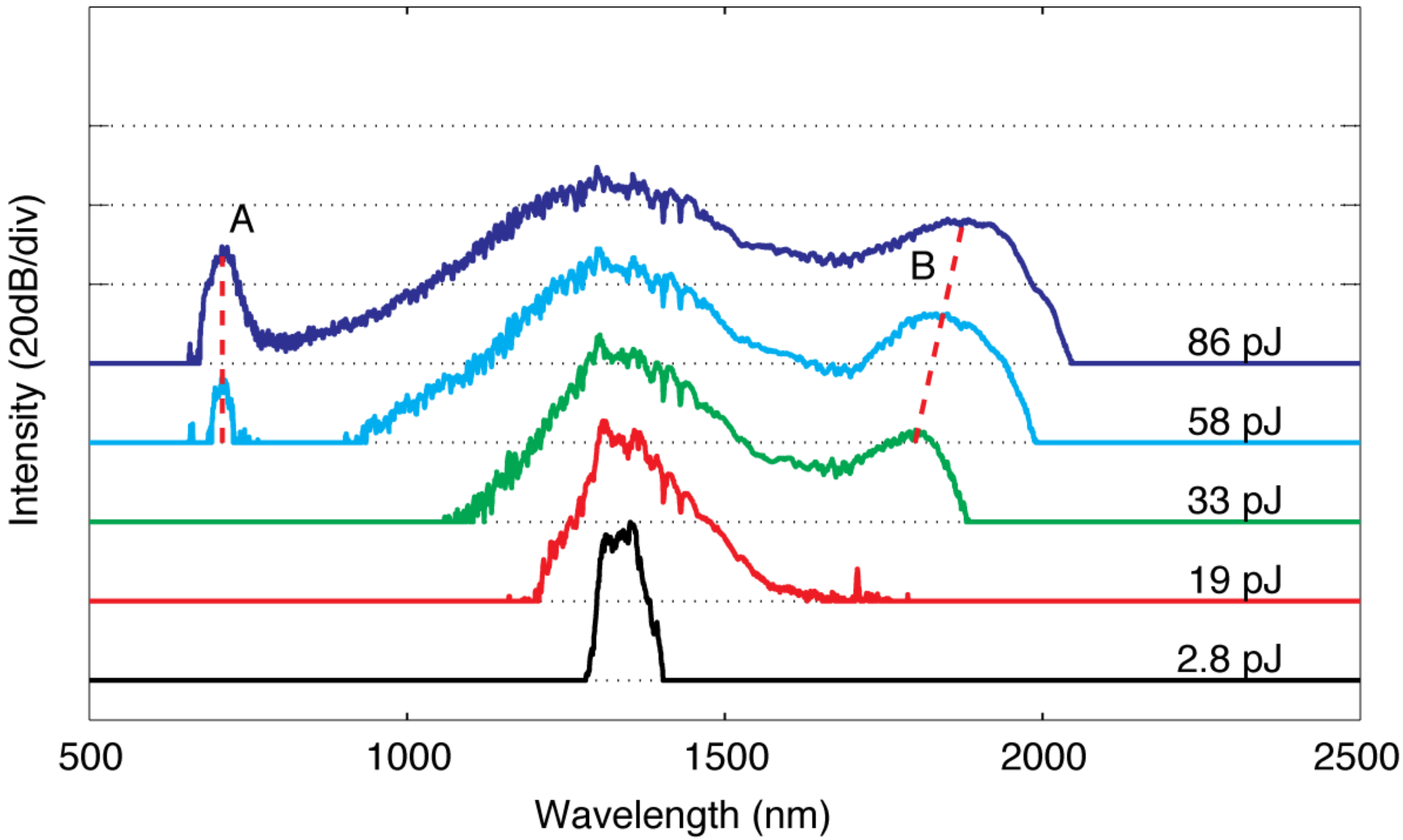


- Peak appears at 1800 nm

  → onset of soliton fission

Halir, Okawachi, Levy, Foster, Lipson, and Gaeta , *Opt. Lett.* (2012).

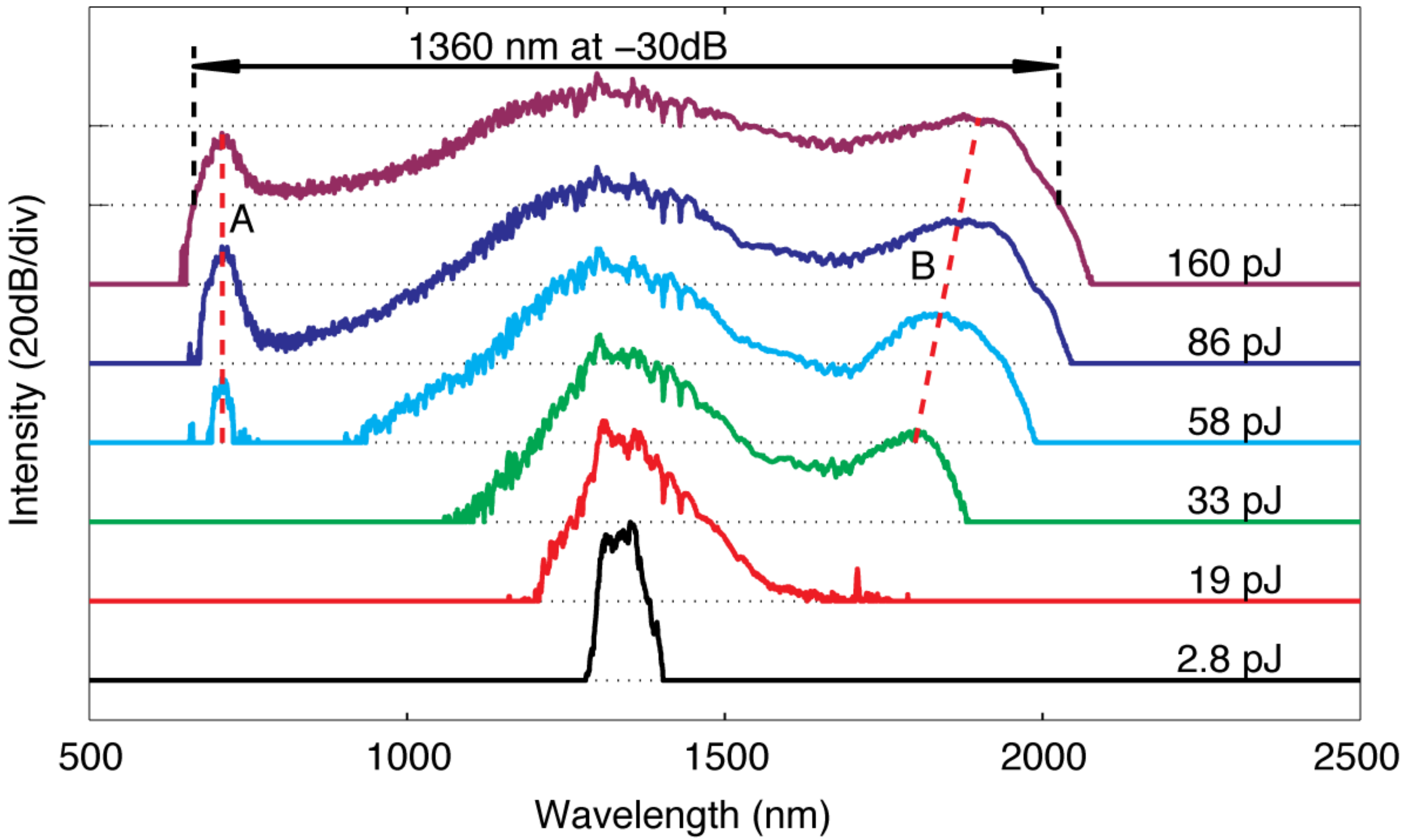
Supercontinuum Generation in Si_3N_4 Waveguide



- Self-frequency shift → 1800 nm peak to higher wavelengths
- Dispersive wave generation at 710 nm seeded by soliton fission

Halir, Okawachi, Levy, Foster, Lipson, and Gaeta , *Opt. Lett.* (2012).

Supercontinuum Generation in Si_3N_4 Waveguide



- Supercontinuum generation spans from 665 nm to 2025 nm

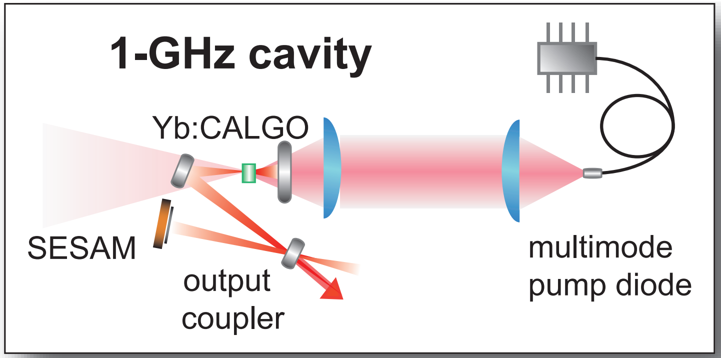
  → 1.6 octave span

Halir, Okawachi, Levy, Foster, Lipson, and Gaeta, *Opt. Lett.* (2012).

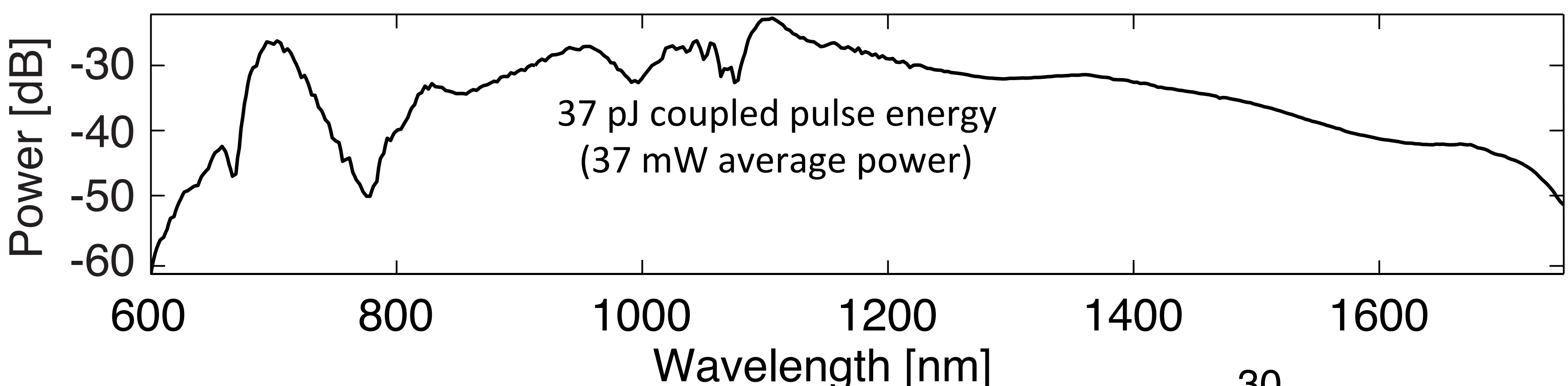
Supercontinuum Generation with Diode-Pumped Solid-State Laser @ 1 μm

Collaboration w/ Ursula Keller's group (ETH-Zurich)

- Pump with 1-GHz repetition rate SESAM-modelocked diode-pumped Yb:CALGO laser
  [Klenner, et al., Opt. Express (2014)]



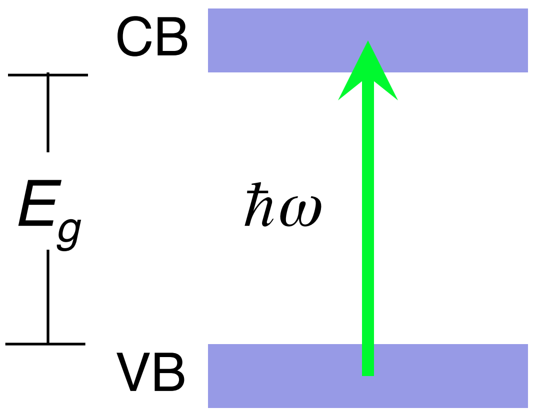
- 92-fs input pulses, 1055 nm center wavelength
- 5-cm-long waveguides



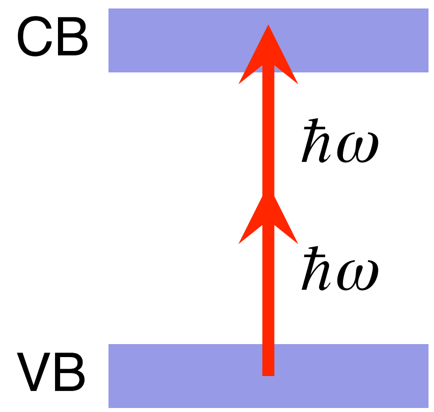
Other Nonlinear Processes: Im{ $\chi^{(3)}$ } – Nonlinear Absorption

- 1- and 2-photon resonances lead to absorption

Saturated Absorption



Two-Photon Absorption



intensity

$$\frac{dI}{dz} = -\alpha_0 \left(1 - \frac{I}{I_s}\right) I$$

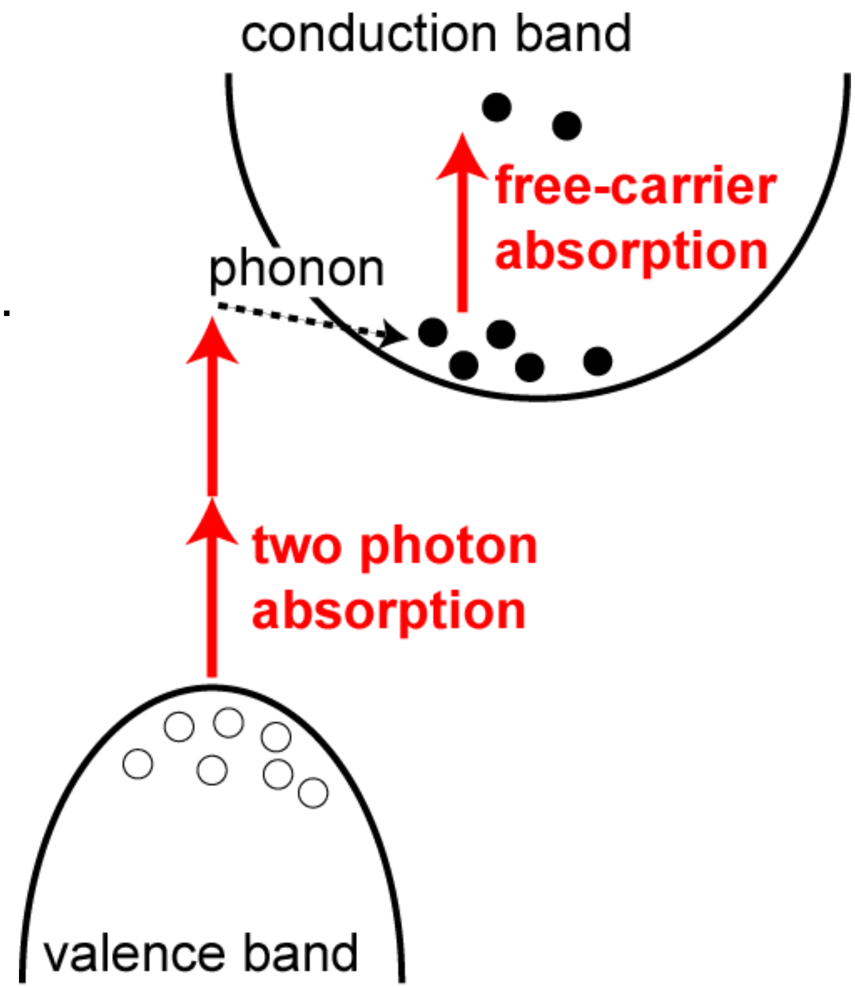
saturation intensity

$$\frac{dI}{dz} = -\beta I^2$$

TPA coefficient

Issue for High-Power Operation: Nonlinear Absorption

- Two-photon absorption generates free carriers.
- Free carriers absorb incoming photons.
- Reduction of free-carrier lifetime can reduce loss.

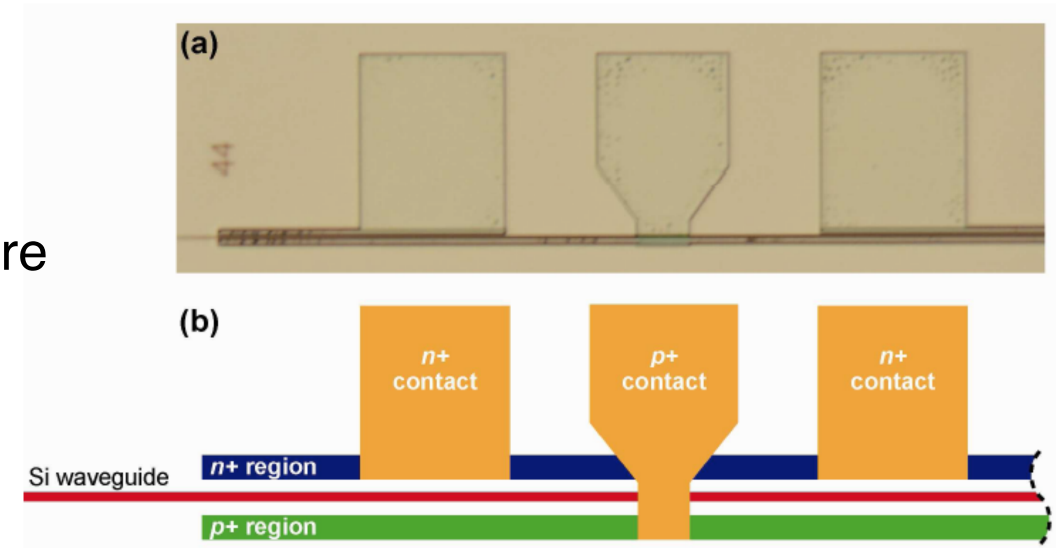


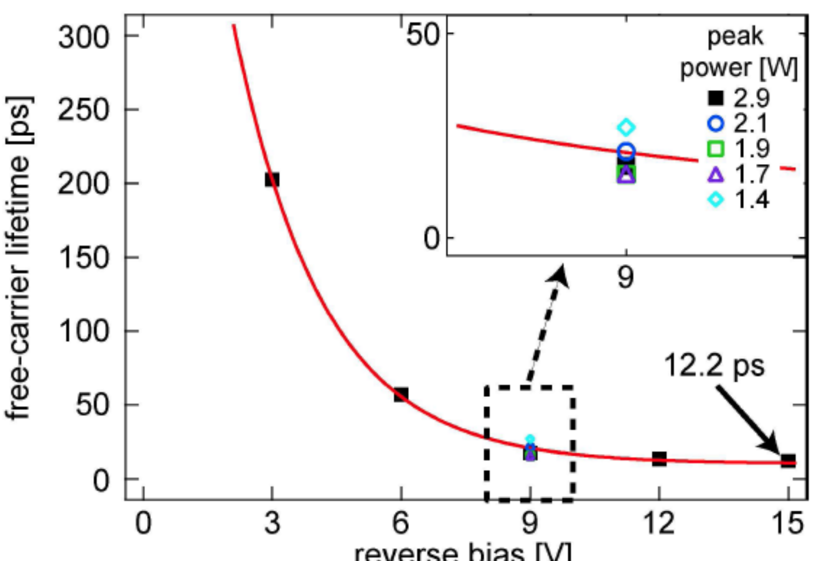
Solution:

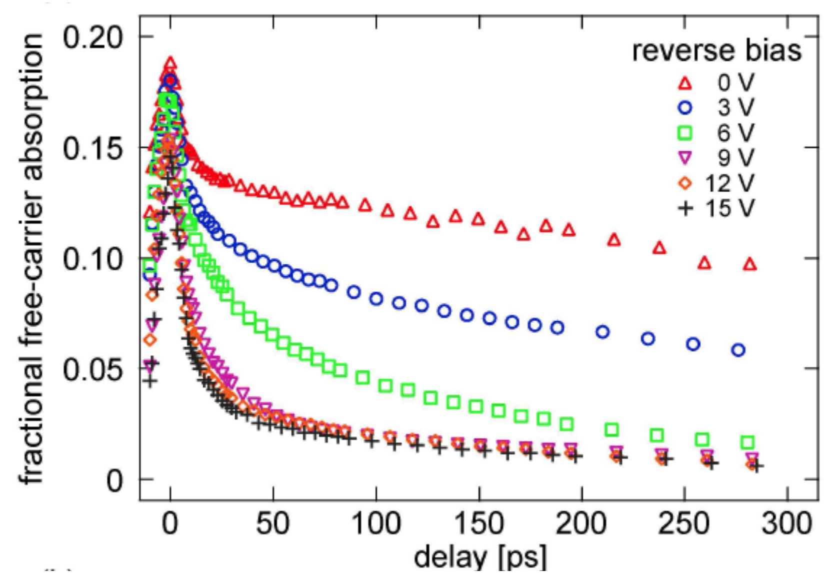
- Integrate PIN-diode structure into waveguides.
- Operate w/ pump > 2 μm
- Use SiN (broader band-gap).

Reduction of Free-Carrier Lifetime

- Incorporate *p-i-n* structure







Effects of Two-Photon Absorption

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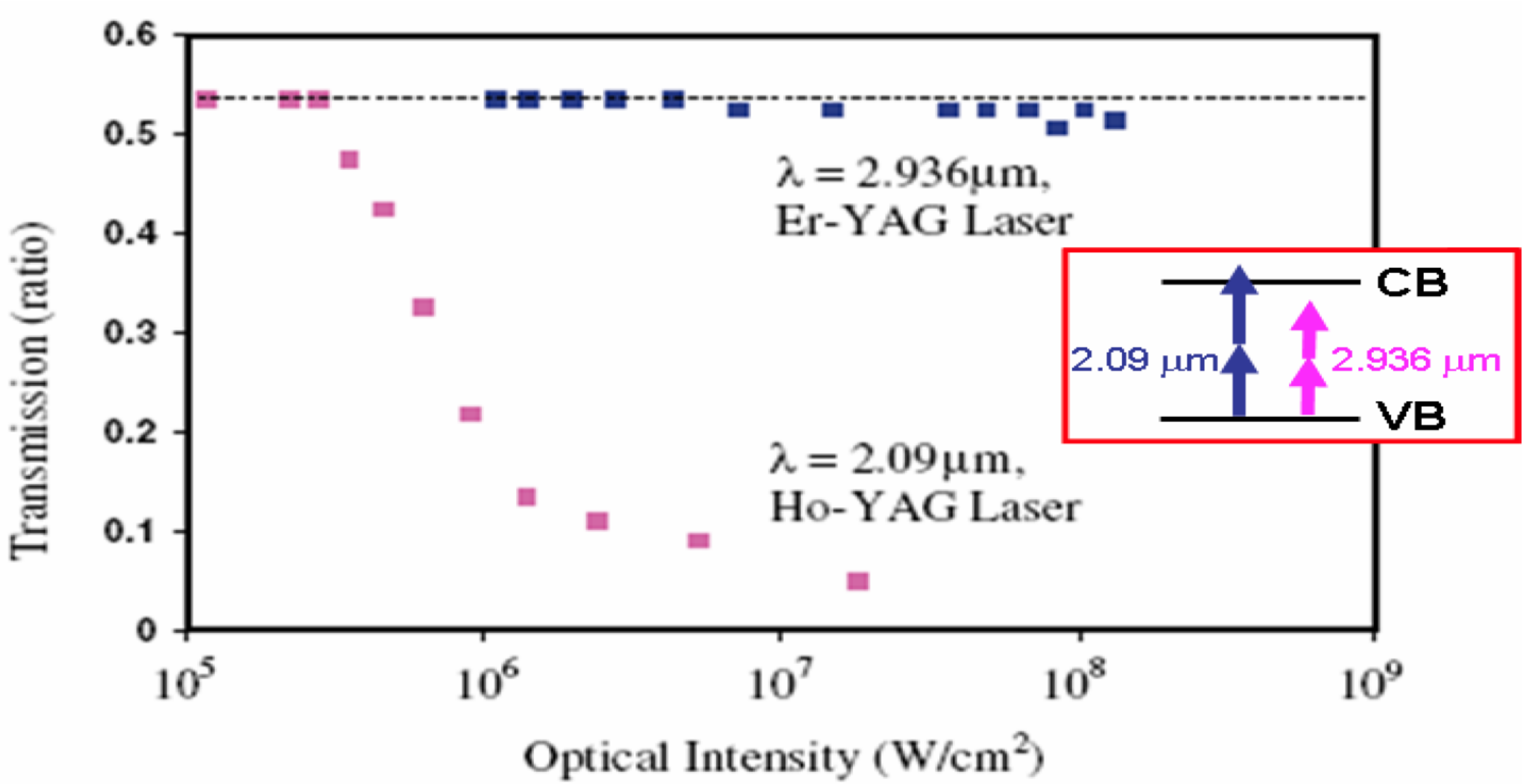
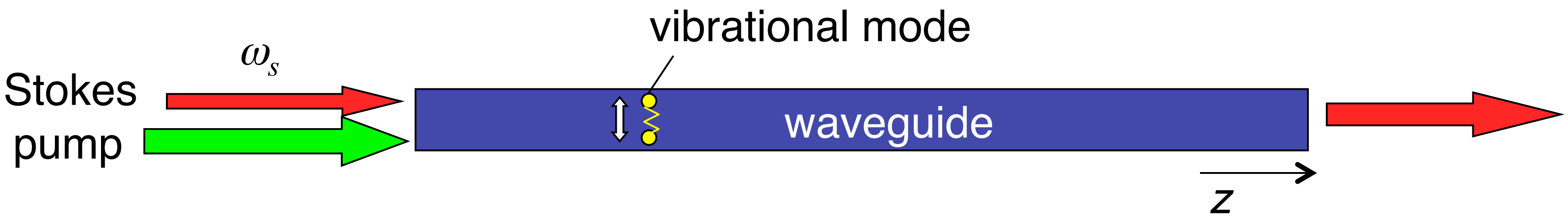
- 1- and 2-photon resonances lead to absorption



Raghunathan, et al. (2010).

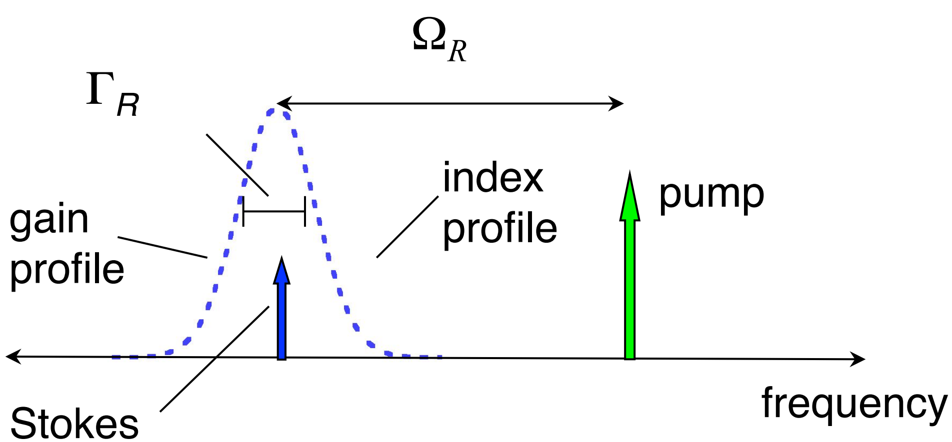
Im{ $\chi^{(3)}$ } – Raman Amplification

- Stimulated Raman scattering produces gain for Stokes wave.



Stokes intensity

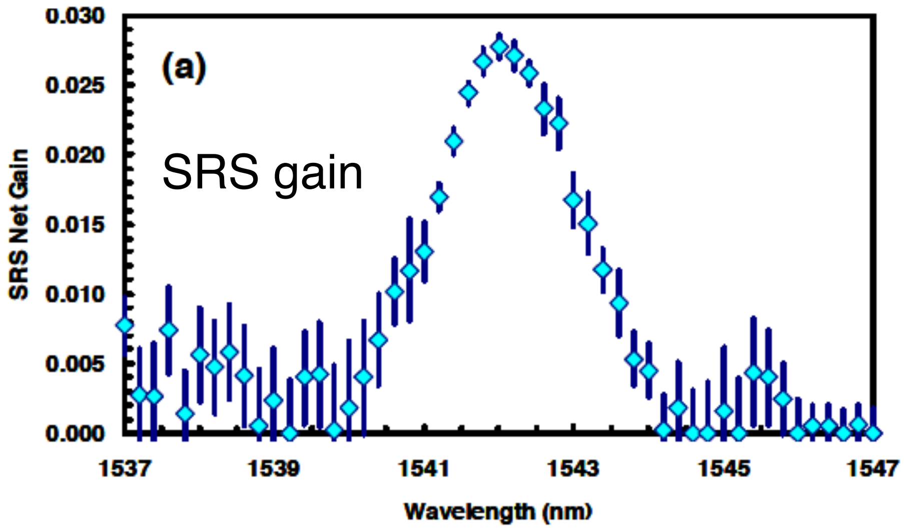
$$\frac{dI_s}{dz} = (g_R I_R) I_s \qquad g_R \propto \mathrm{Im}\left\{\chi_R^{(3)}\right\}$$

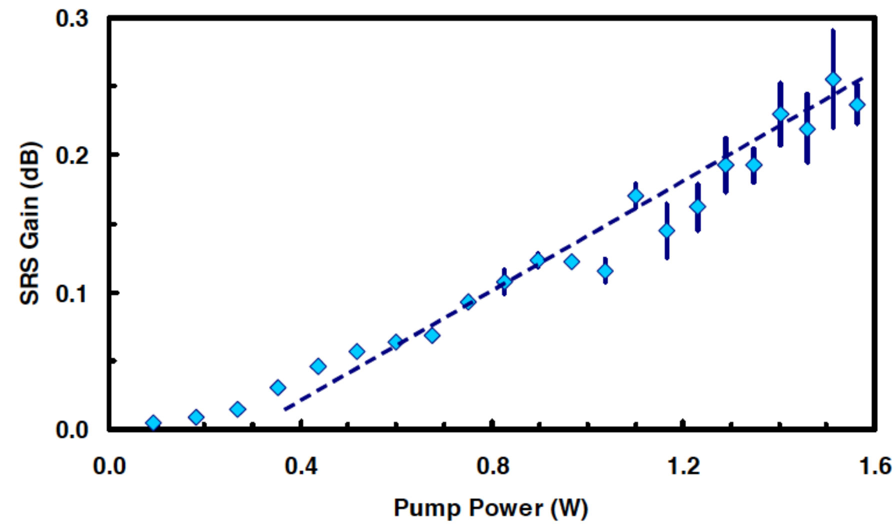


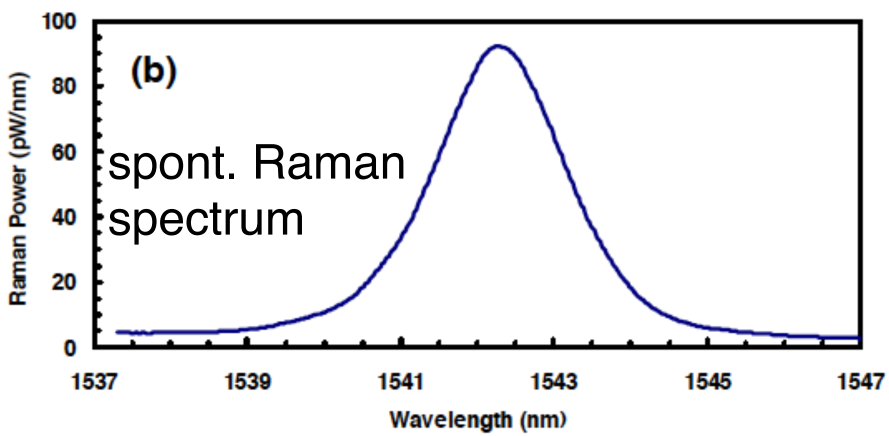
Typical Raman values

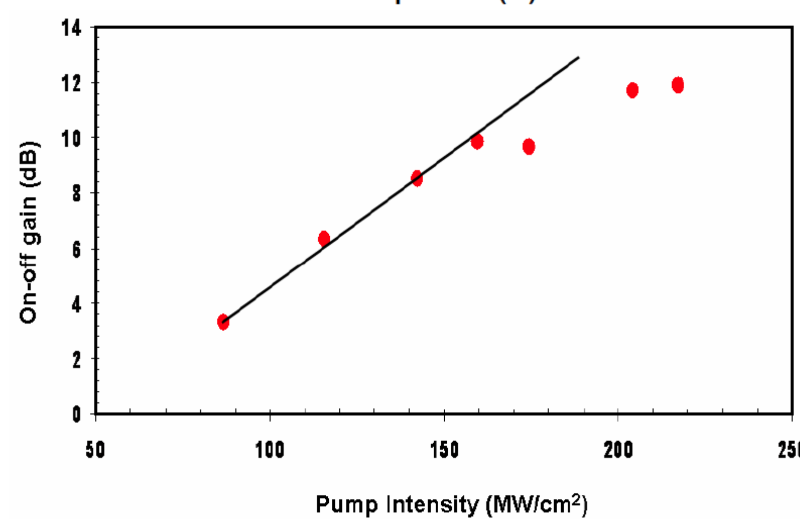
Silicon	**SiO_2**
$\Gamma_R \sim$ 100 GHz	$\Gamma_R \sim$ 3 THz
$\Omega_R \sim$ 13 THz	$\Omega_R \sim$ 12 THz

Raman Gain in Silicon-Based Nanowaveguides









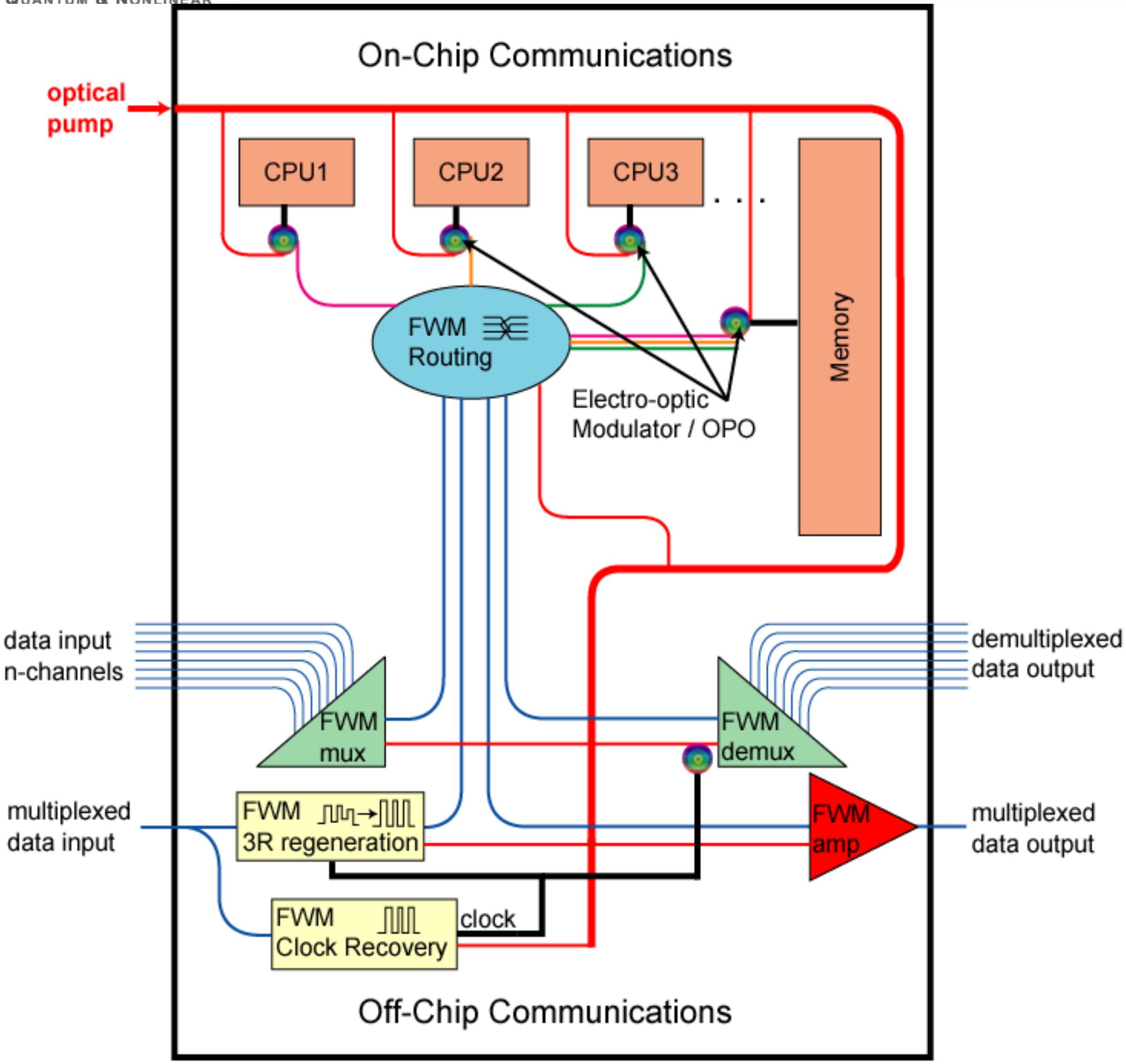
Claps, Dimitropoulos, Raghunathan, Han and Jalali, Opt. Express **11,** 1731 (2003).

Outline: Nonlinear Nanophotonics I

Lecture I

- Brief review of linear & nonlinear optics waveguides
- Nonlinear processes in nanowaveguides
- Four-wave mixing (FWM) in Si nanowaveguides
  - Dispersion engineering
  - Ultra-broadband wavelength conversion
  - Applications: correlated photons, signal regeneration

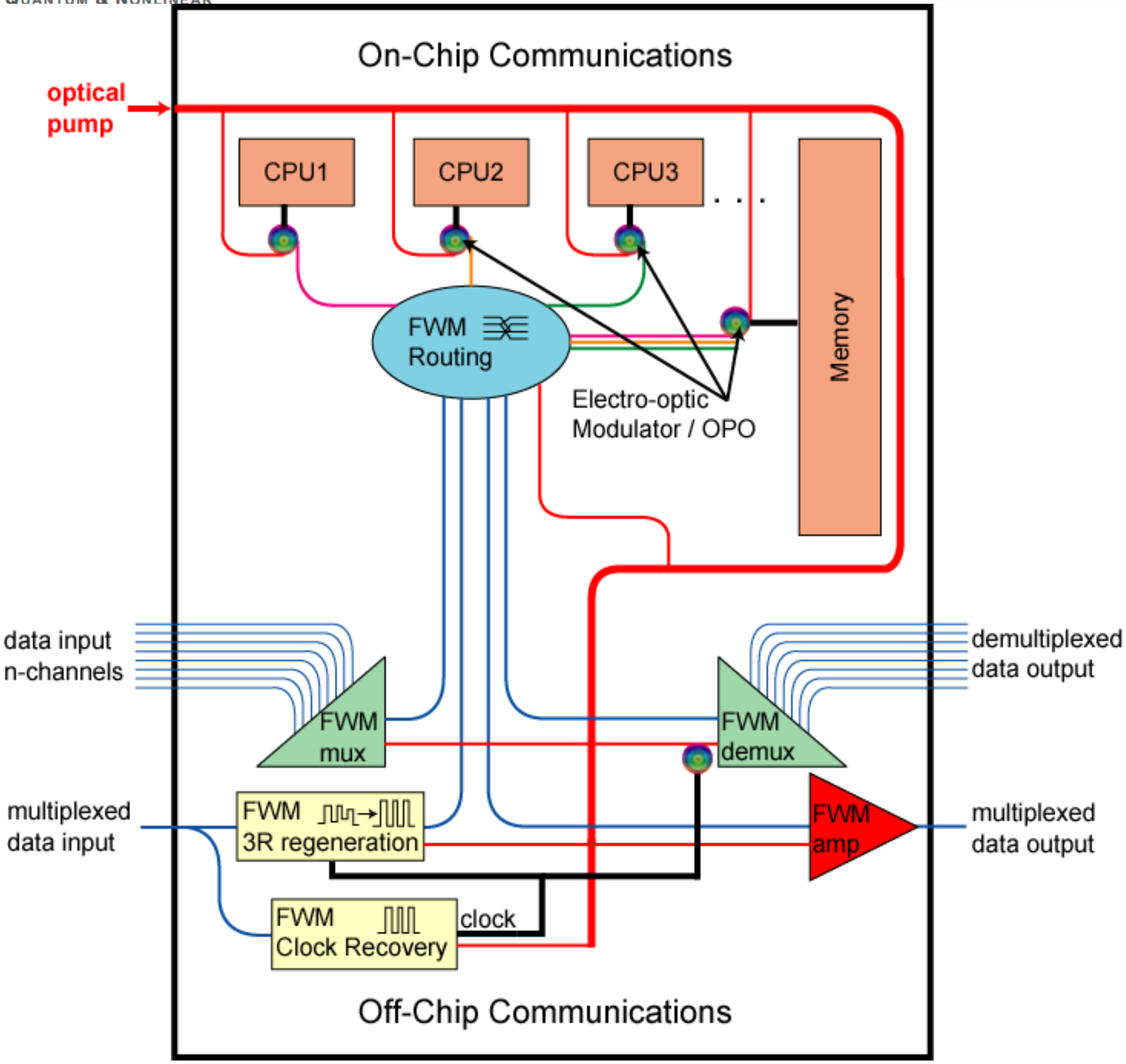
Nonlinear Photonics on Silicon Chip



On-Chip Processing

- Multiplexing/demux
- Regeneration
- Optical buffers
- Routing (switching / logic)
- Multicasting
- A-D conversion
- Wavelength conversion
- Amplification
- Oscillator/comb source

Nonlinear Photonics on Silicon Chip

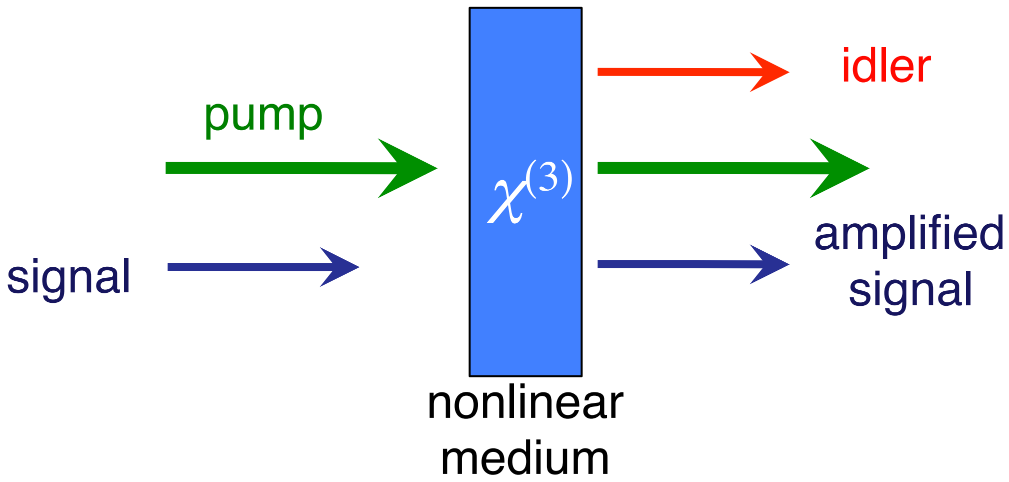


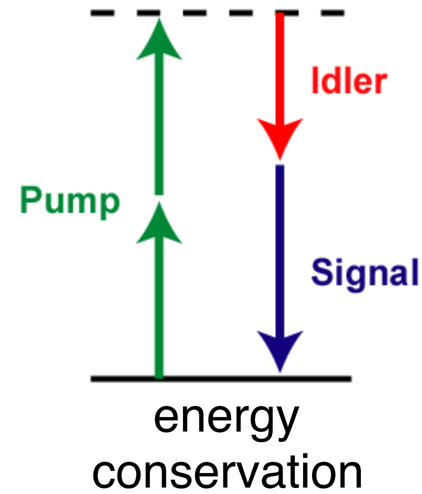
On-Chip Processing

- Multiplexing/demux
- Regeneration
- Optical buffers
- Routing (switching / logic)
- Multicasting
- A-D conversion
- Wavelength conversion
- Amplification
- Oscillator/comb source

All performed via four-wave mixing.

Four-Wave Mixing





<u>input field</u>

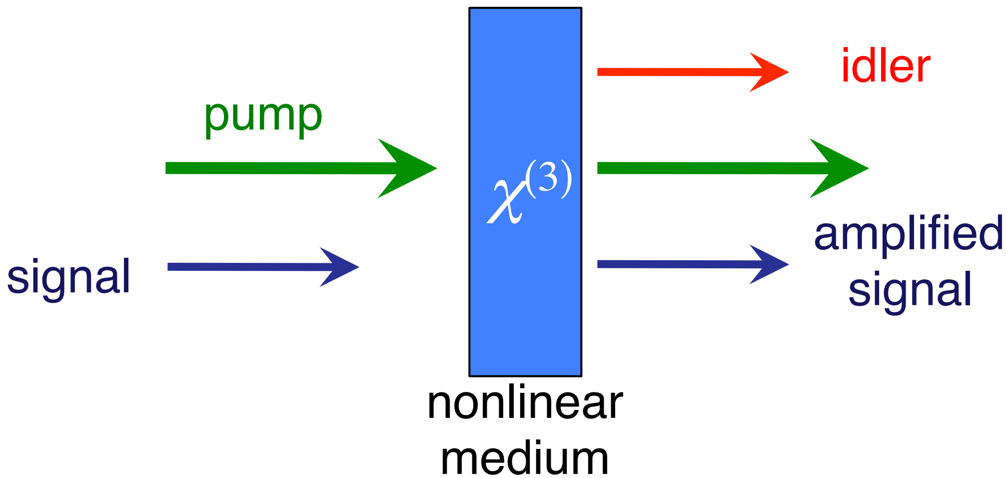
$$E_{input} = E_p + E_s = A_p e^{-i\omega_p t} + A_s e^{-i\omega_s t} + c.c.$$

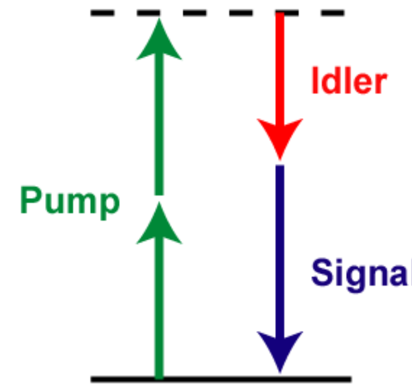
<u>nonlinear polarization</u>

$$P^{(3)} = \chi^{(3)} E^3 = \underbrace{\chi^{(3)} A_p^2 A_s^* e^{-i(2\omega_p - \omega_s)t}}_{\text{idler driving term}} + \text{other terms}$$

$$\omega_i = 2\omega_p - \omega_s$$

Four-Wave Mixing





energy conservation

<u>input field</u>

$$E_{input} = E_p + E_s = A_p e^{-i\omega_p t} + A_s e^{-i\omega_s t} + c.c.$$

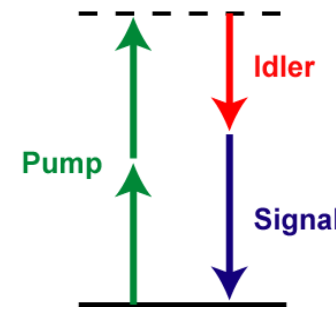
<u>nonlinear polarization</u>

$$P^{(3)} = \chi^{(3)} E^3 = \chi^{(3)}\left[\underbrace{A_p^2 A_s^*}_{\text{idler driving term}} + \underbrace{2\,|A_p|^2 A_i}_{\text{cross-phase modulation}}\right] e^{-i(2\omega_p - \omega_s)t}$$

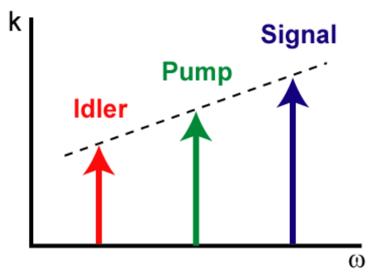
- Efficient generation requires momentum conservation (i.e., phase matching)

Phase Matching in Four-Wave Mixing

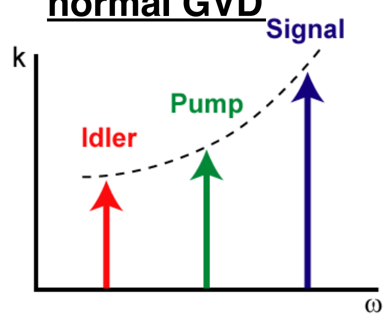
- Energy conservation: $2\omega_p - (\omega_s + \omega_i) = 0$
- Momentum conservation: $\Delta k = 2k_p - (k_s + k_i) + \Delta k_{nl}$
  - Balance of GVD and effects of self-phase modulation & cross-phase modulation
  - Want $\Delta k_L\ L < 1$



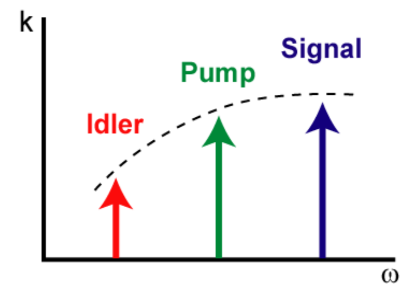
No dispersion, no SPM/XPM



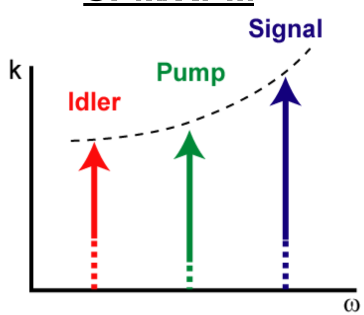
normal GVD



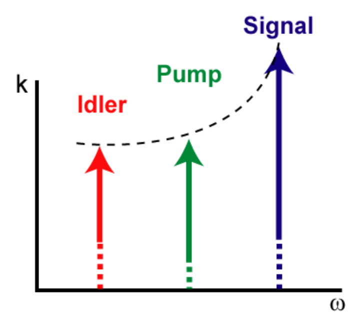
anomalous GVD



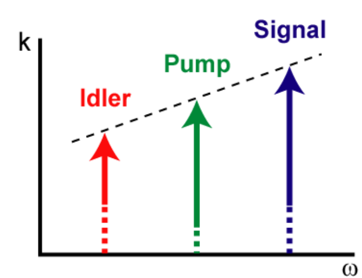
SPM/XPM



normal GVD + SPM/XPM



anomalous GVD + SPM/XPM



Requirements for Efficient Four-Wave Mixing

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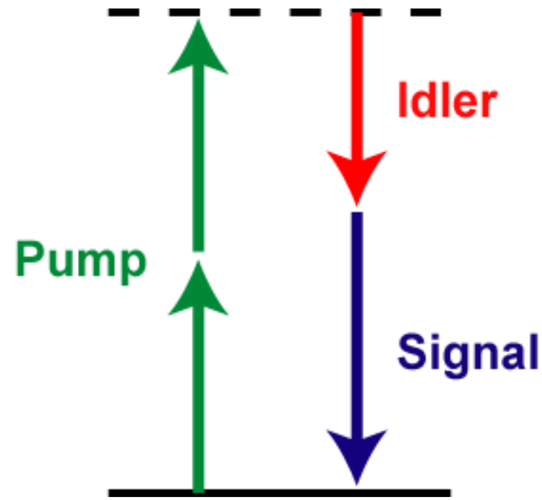
COLUMBIA UNIVERSITY



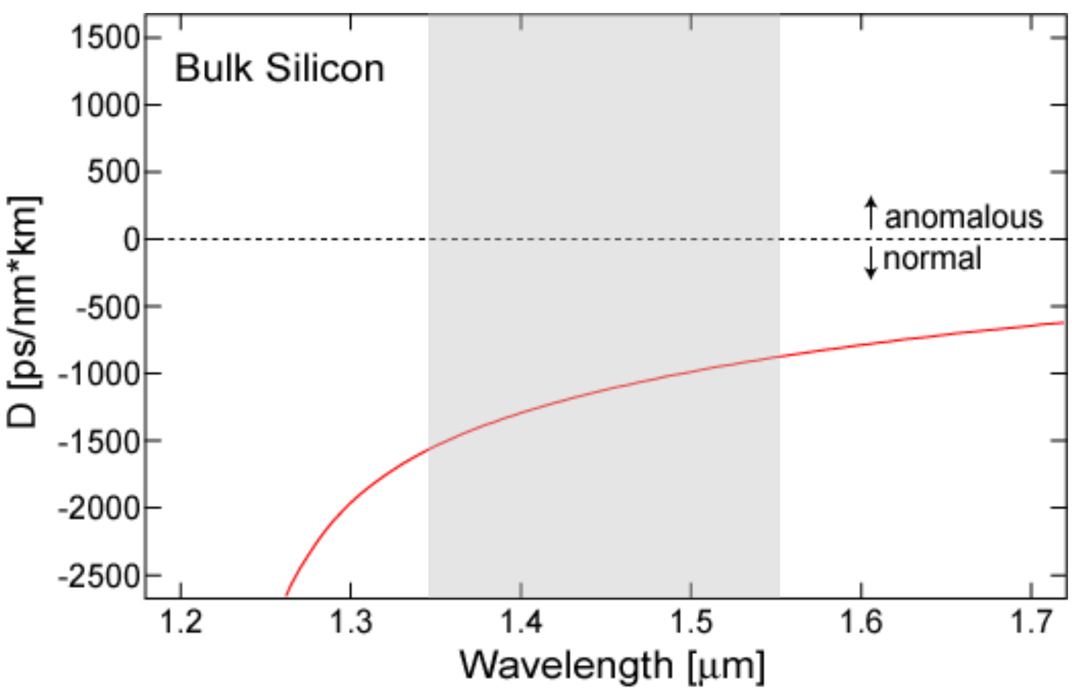
- Energy conservation: $2\omega_p - (\omega_s + \omega_i) = 0$
- Momentum conservation: $\Delta k = 2k_p - (k_s + k_i) + \Delta k_{nl}$
  - Balance of GVD and effects of self-phase modulation & cross-phase modulation

group-velocity dispersion: $\boxed{\mathrm{GVD} \propto -\dfrac{d^2 n}{d\lambda^2} \geq 0}$

Challenge: Large Normal GVD of Si

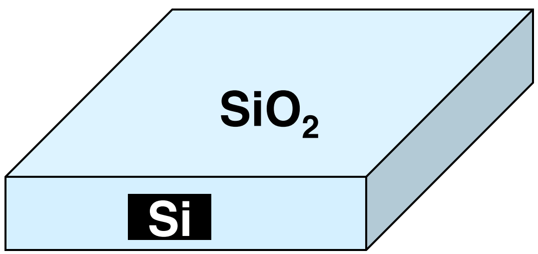
- Bulk Silicon
  - absorption band edge @ 1.1 μm
  - Si @ 1.55 μm: ***D*** **~ − 1000 ps/(nm*km)**
    [silica glass @ 1.5 μm: ***D*** **~ 20 ps/(nm*km)**]

GVD



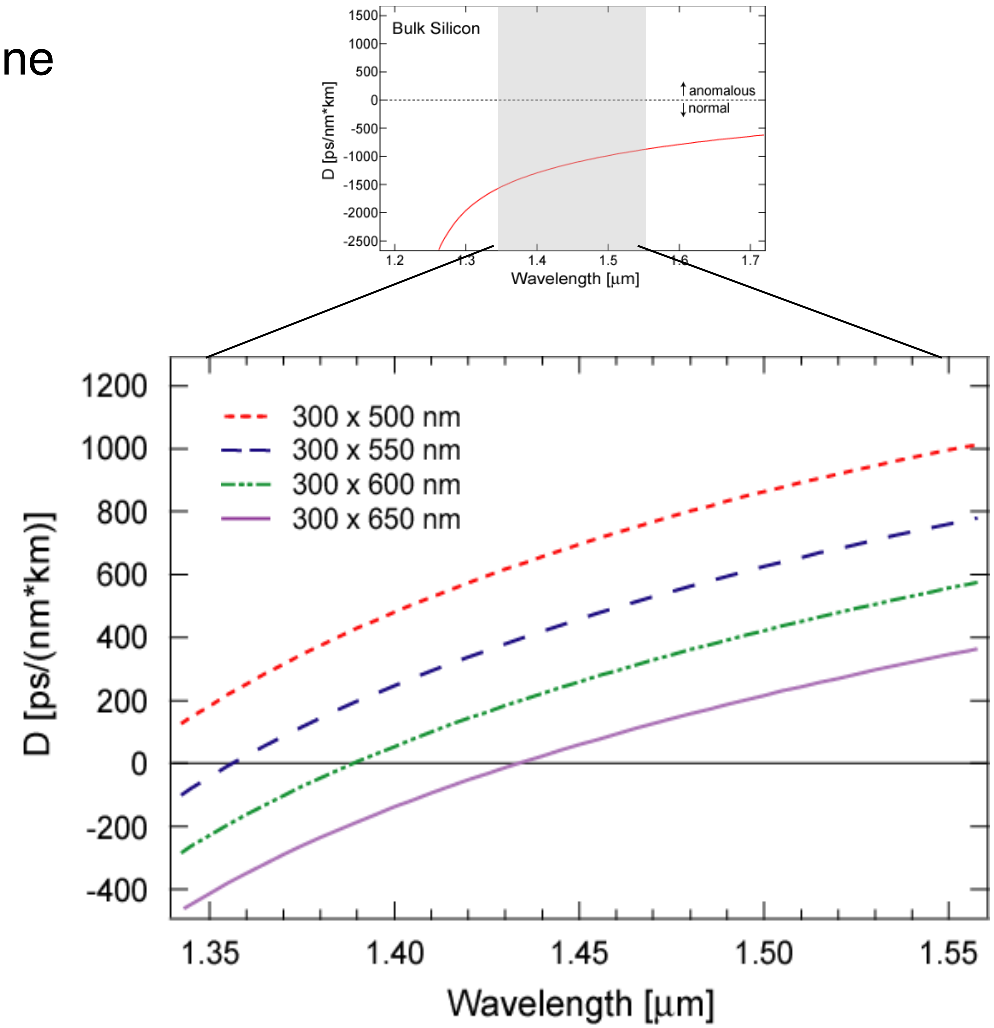
Tailoring of GVD in Si Waveguides

- Utilize waveguide dispersion to tune GVD.



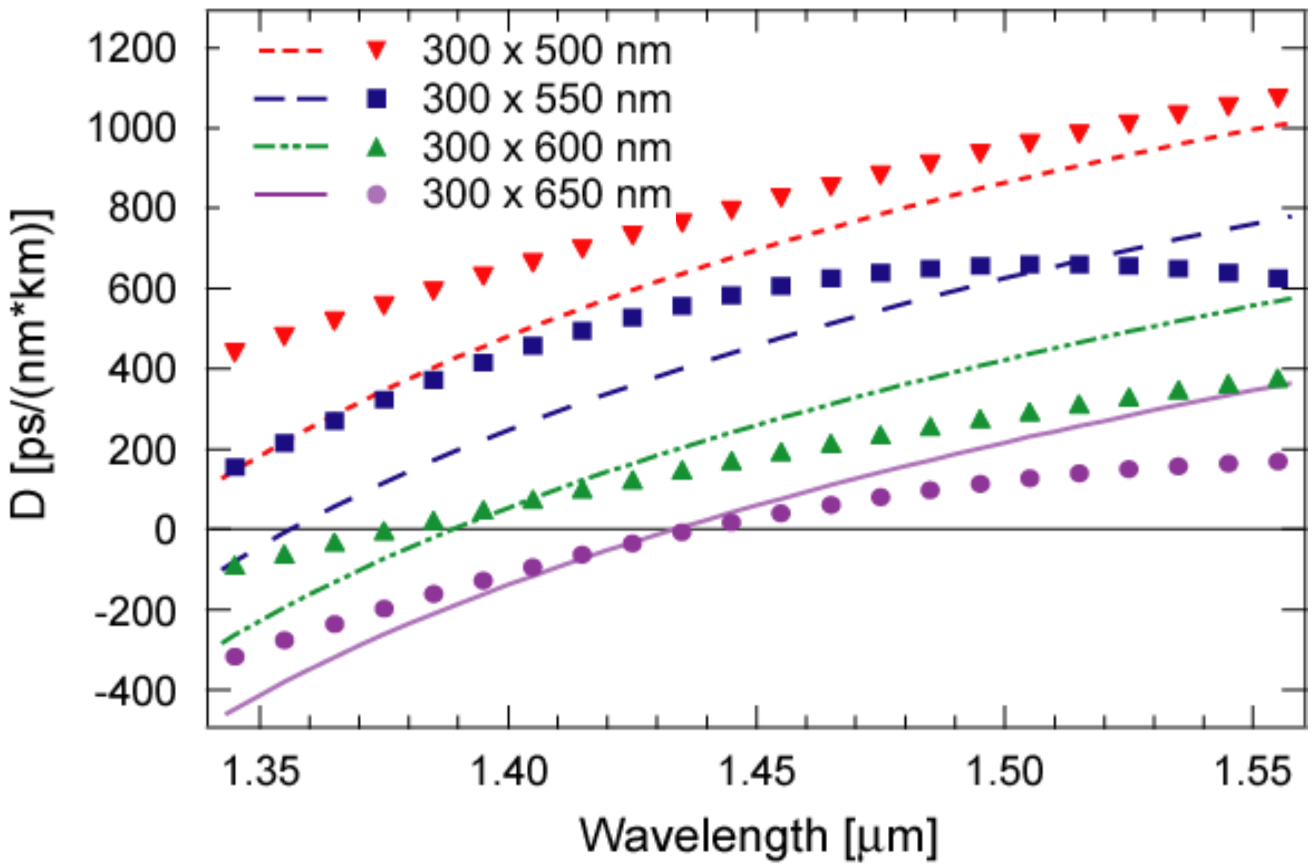
- GVD can be tuned by varying waveguide shape and size.

Turner et al. (2006)
Lin et al. (2006)



Predicted anomalous-GVD ~50X SMF-28 fiber [20 ps/(nm·km)].

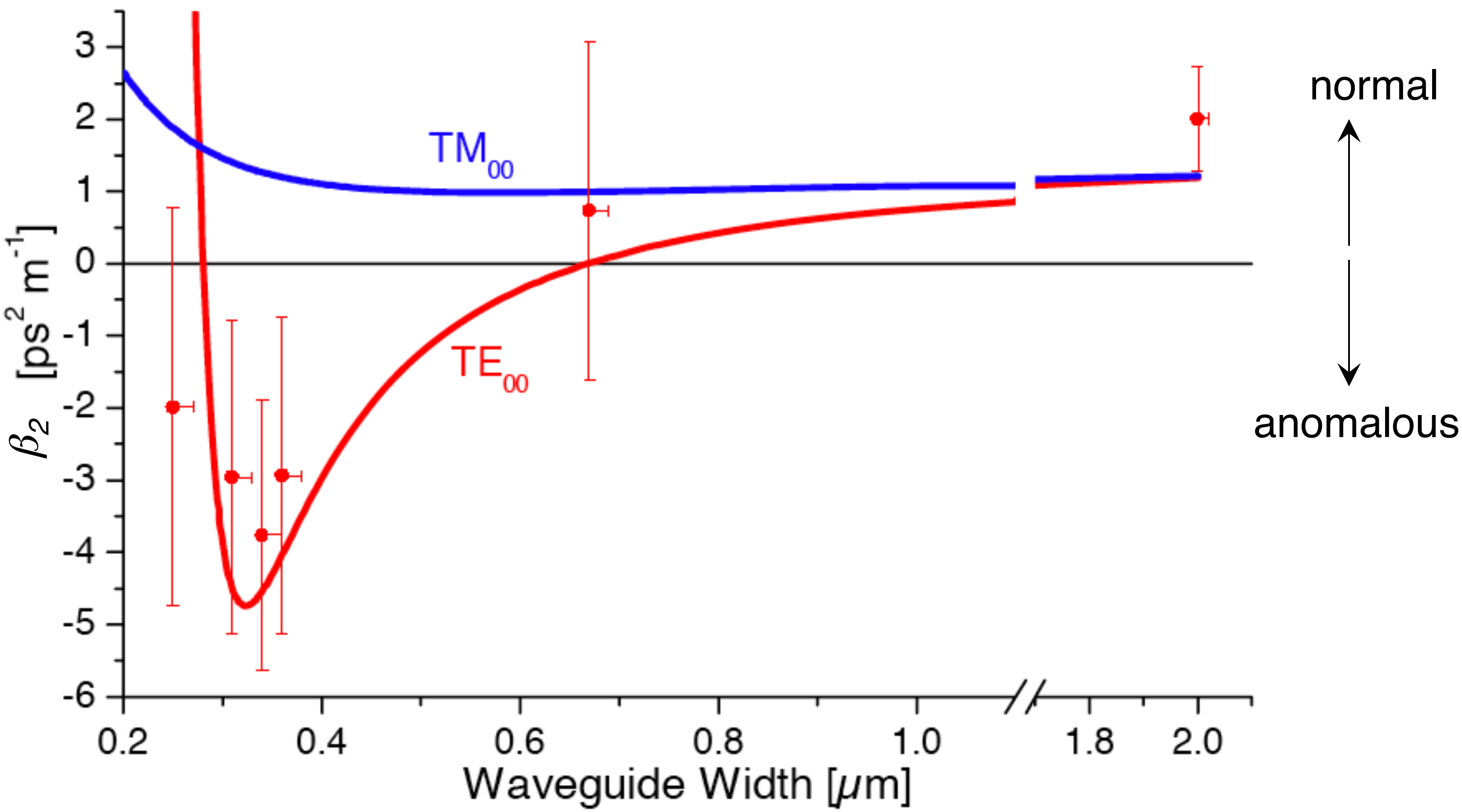
Measurement of Anomalous-GVD in Si Waveguides



Turner, Manolatou, Schmidt, Lipson, Foster, Sharping, and Gaeta, *Opt. Express* **14**, 4357 (2006).

Dulkeith, Xia, Schares, Green, and Vlasov, *Opt. Express* **14**, 3853 (2006).

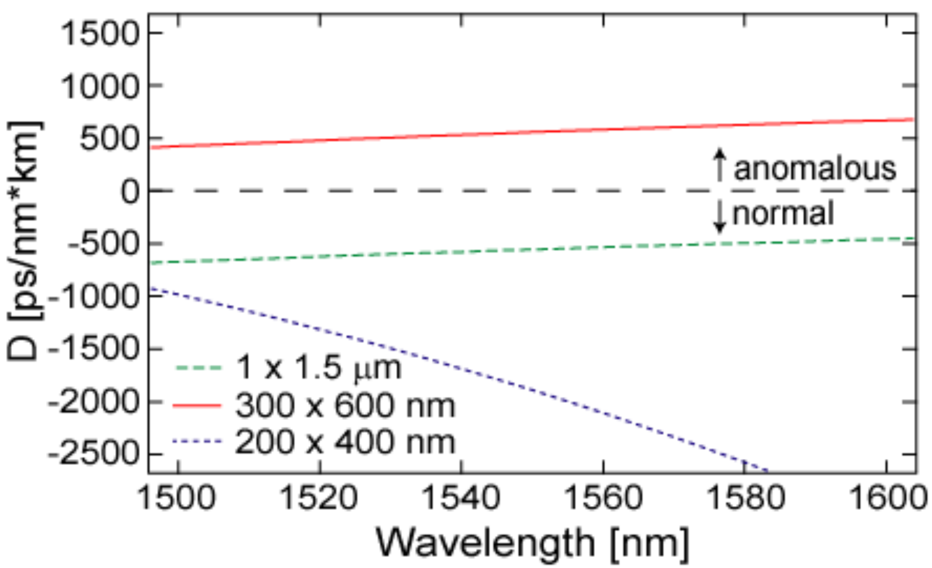
Dispersion Control in AlGaAs Waveguides

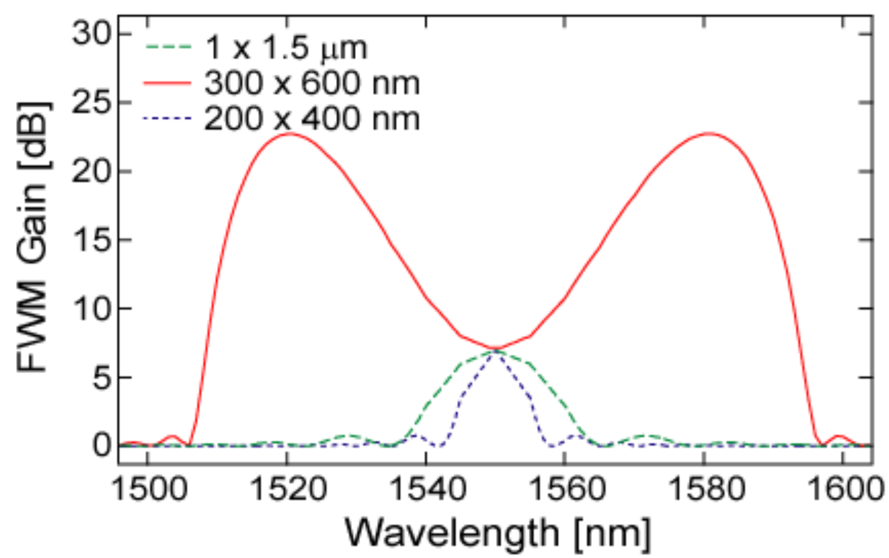


Meier, Mohammed, Jugessur, Qian, Mojahedi, and Aitchison, *Opt. Express* **15**, 12755 (2007).

Phase-Matched Four-Wave Mixing in Si

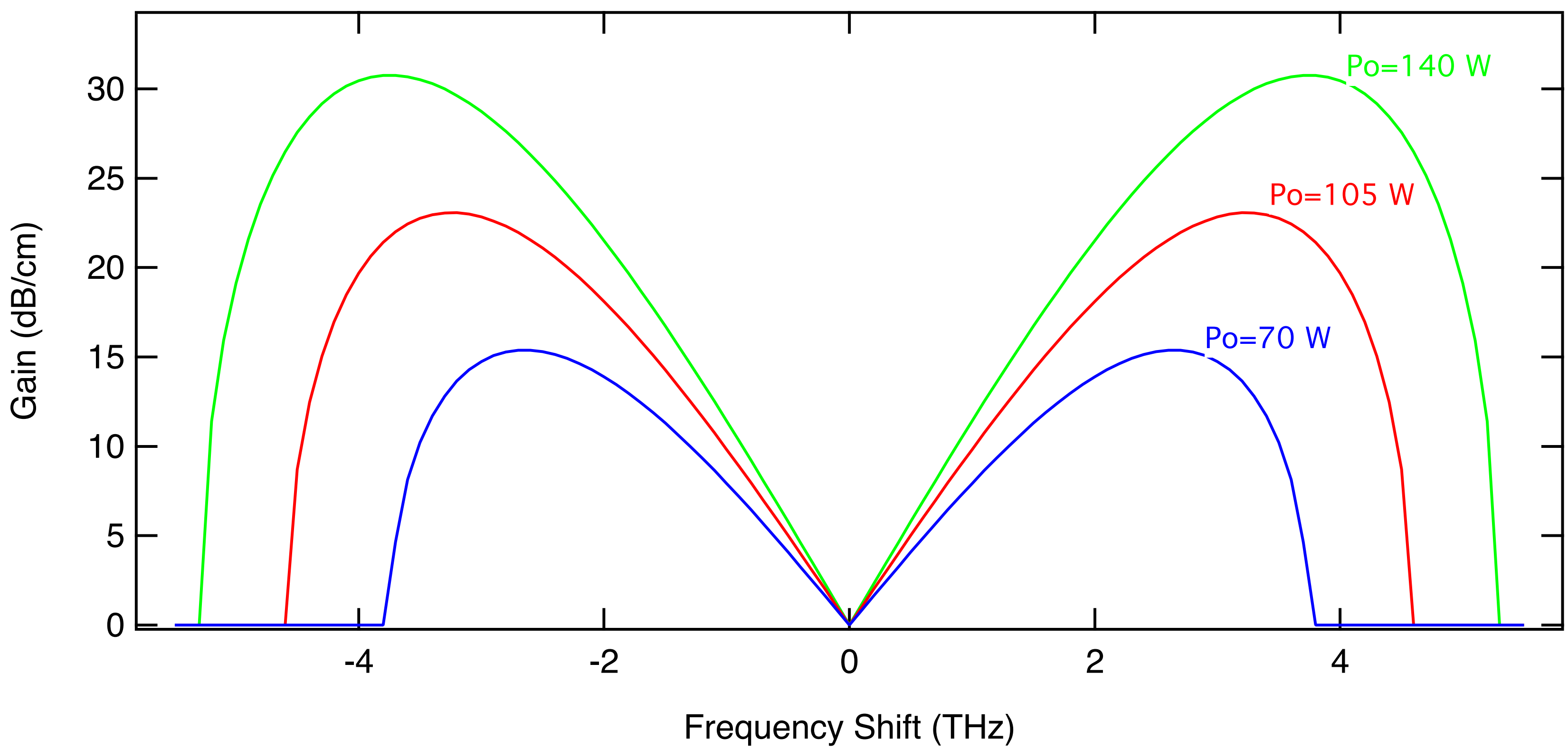
- Broad regions of FWM gain predicted.



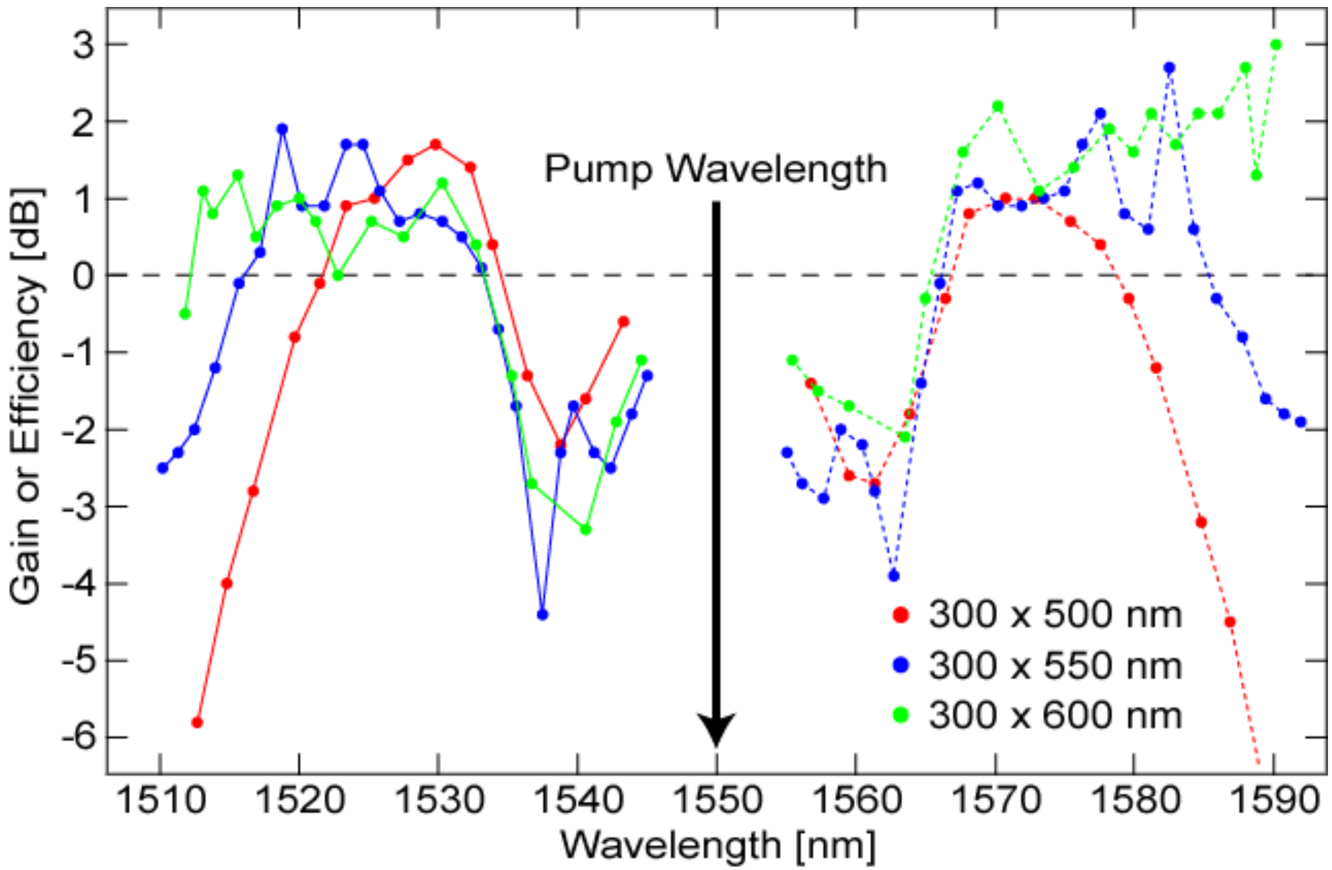


Phase-Matched Four-Wave Mixing

- Peak gain occurs where $\Delta k = 0$



Four-Wave Mixing Amplification



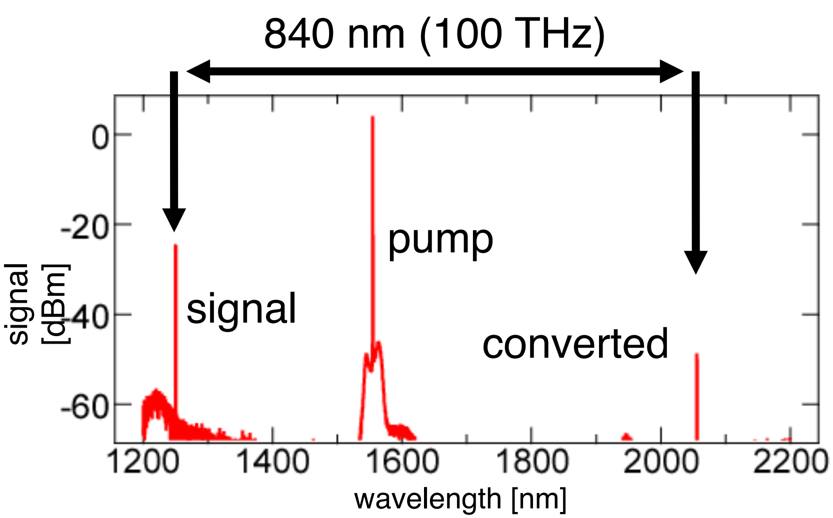
- First observation of broadband gain in Si. (Raman gain bandwidth ~ 1 nm)

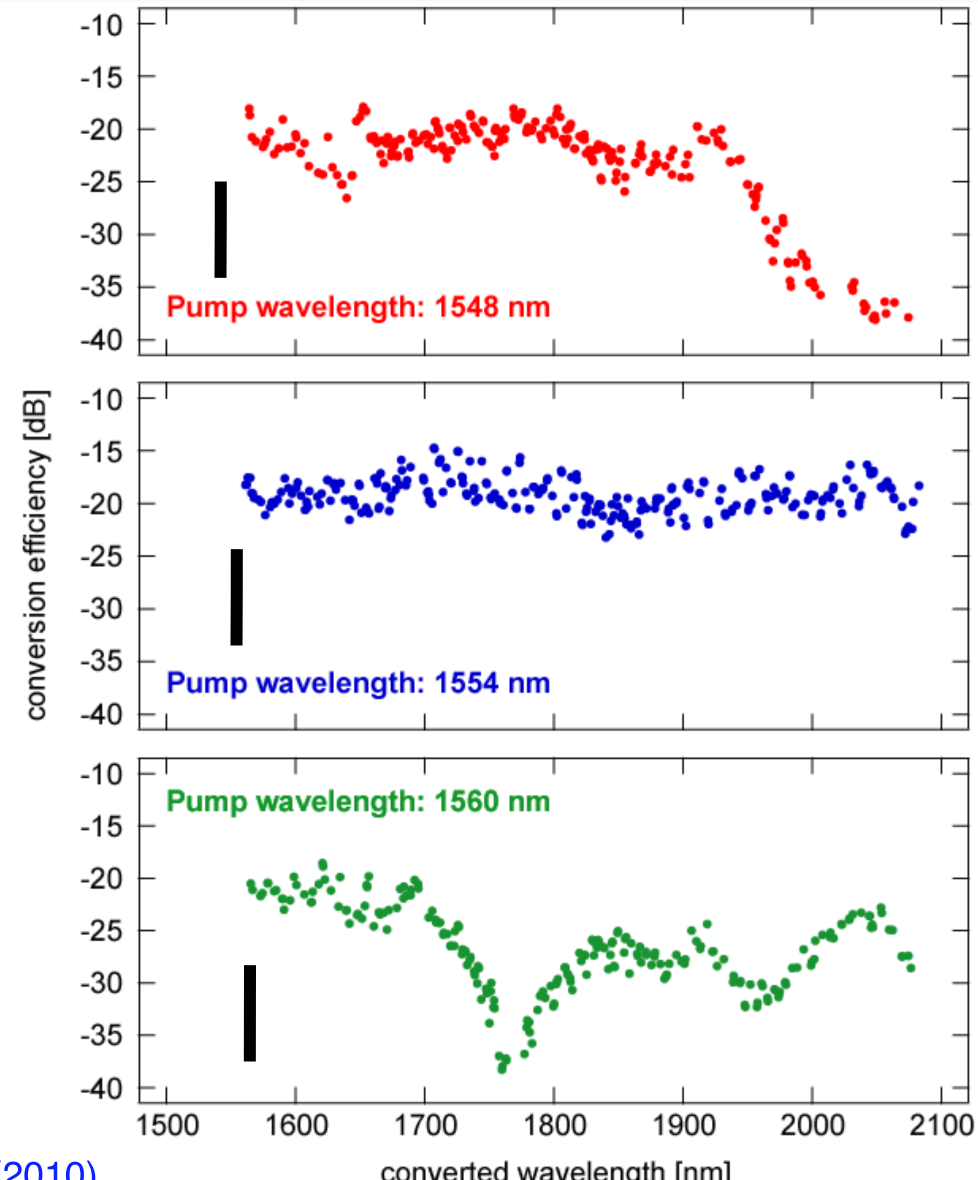
Foster, Turner, Sharping, Schmidt, Lipson, and Gaeta, *Nature* **441**, 960 (2006).

CW Wavelength Conversion over 900-nm Bandwidth

- Pump: 50 mW

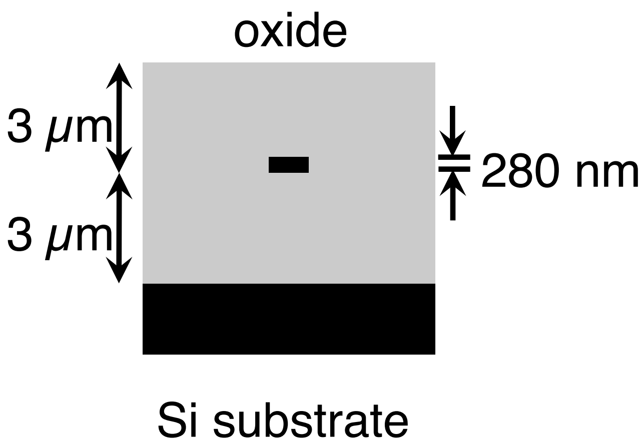
- **Conversion bandwidth > 2/3 of an octave!**



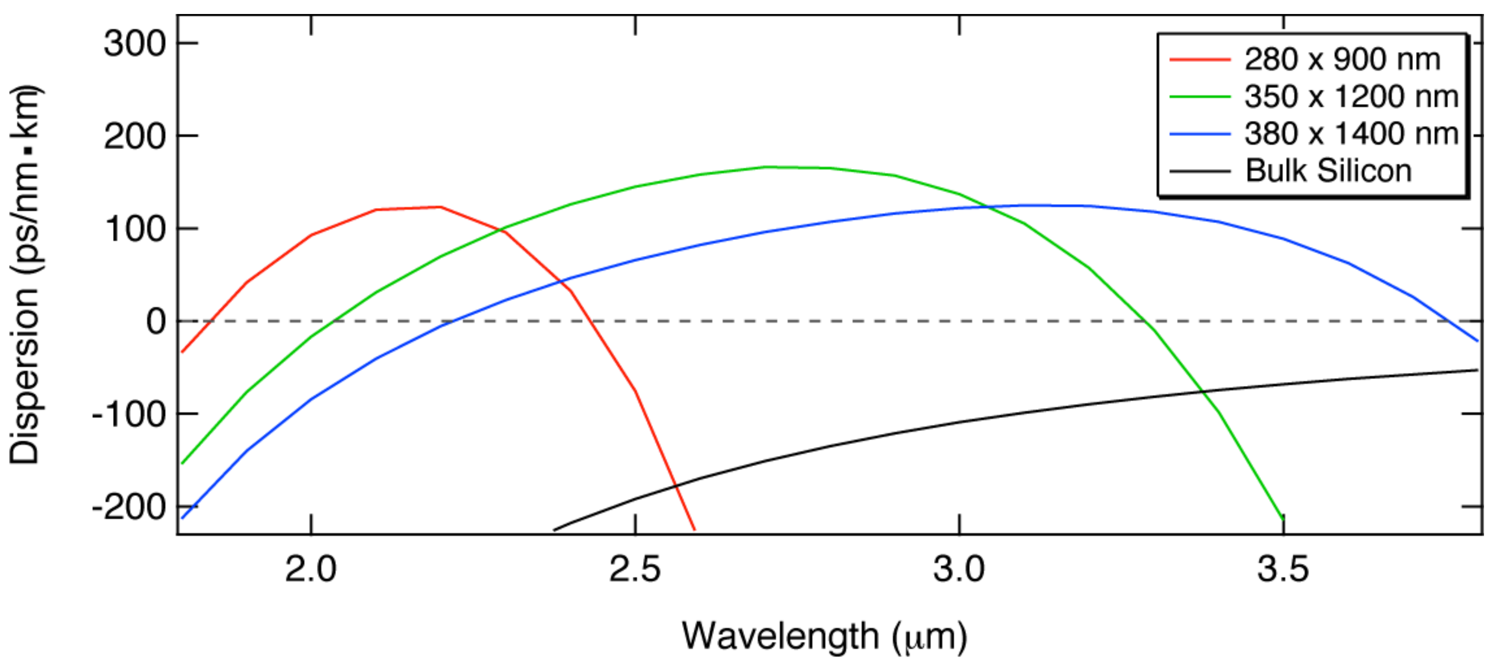


Turner, Lipson, Foster, and Gaeta, *Opt. Express* (2010).

Dispersion Engineering into Mid-IR

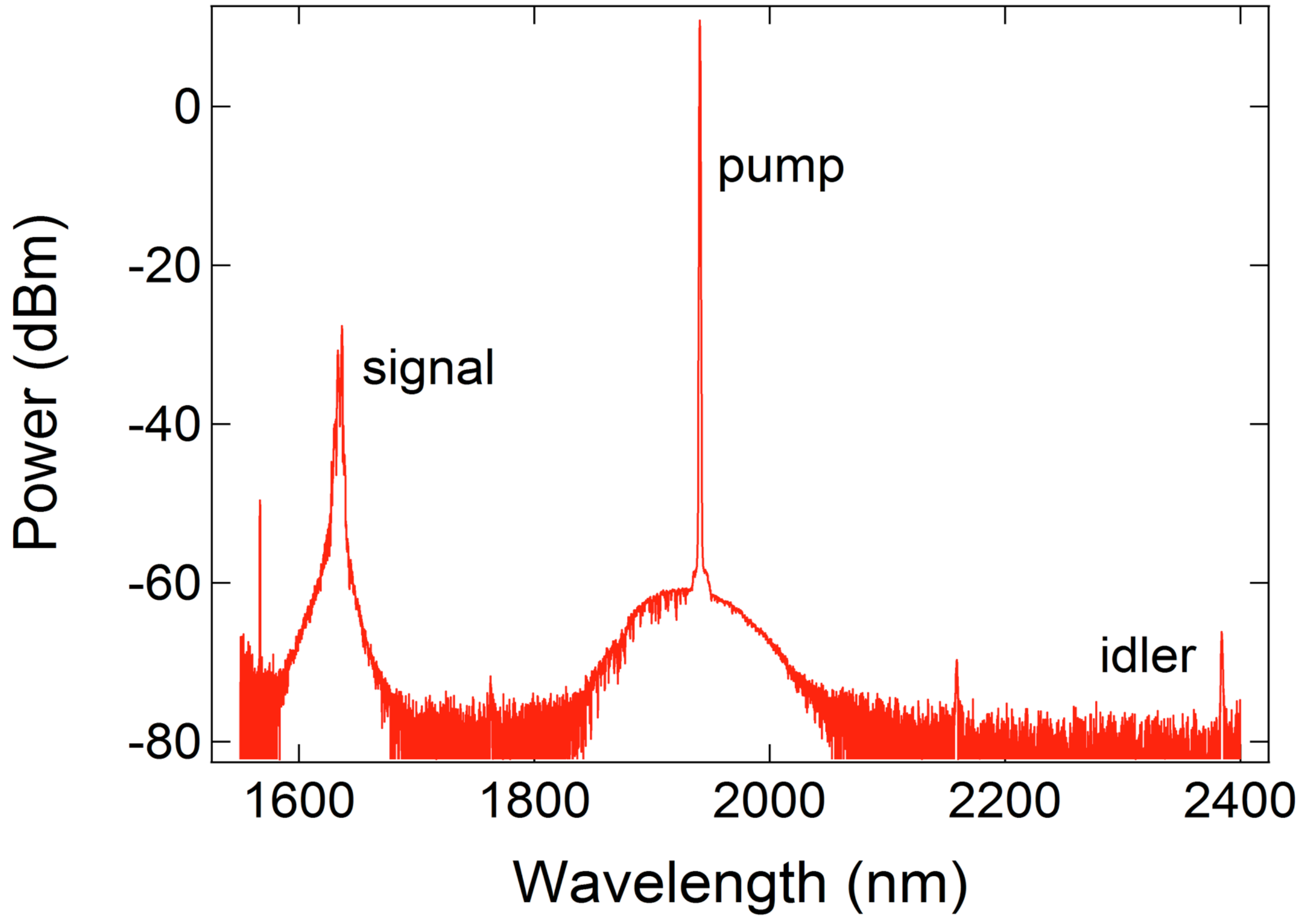


- Broadband anomalous GVD in MIR.



Mid-IR Frequency Conversion

Lau, et al., Lipson, and Gaeta, *Opt. Lett.* (2011).



- Pulsed conversion (w/ gain) [Zlatanovic et al. (2010); Kuyken et al. (2010, 2011).]
- Need other cladding materials (e.g., sapphire, SiN) for longer MIR wavelengths [Baehr-Jones et al. (2010)]

Four-Wave Mixing Amplification in Mid-IR

November 15, 2011 / Vol. 36, No. 22 / OPTICS LETTERS 4401

50 dB parametric on-chip gain in silicon photonic wires

Bart Kuyken,[1,†] Xiaoping Liu,[2,4,†] Günther Roelkens,[1] Roel Baets,[1] Richard M. Osgood, Jr.,[2] and William M. J. Green[3,*]

[1]*Photonics Research Group, Department of Information Technology, Ghent University—imec, Ghent B-9000, Belgium*

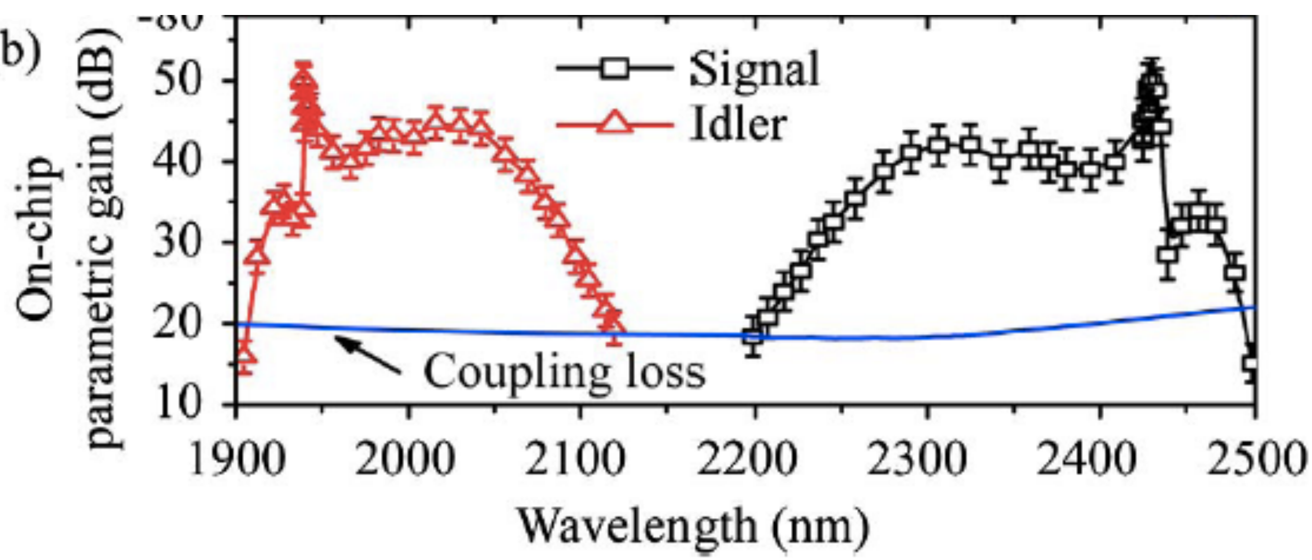
[2]*Department of Electrical Engineering, Columbia University, 1300 S. W. Mudd Building, 500 W. 120th Street, New York, New York 10027, USA*

[3]*IBM Thomas J. Watson Research Center, 1101 Kitchawan Road, Yorktown Heights, New York 10598, USA*

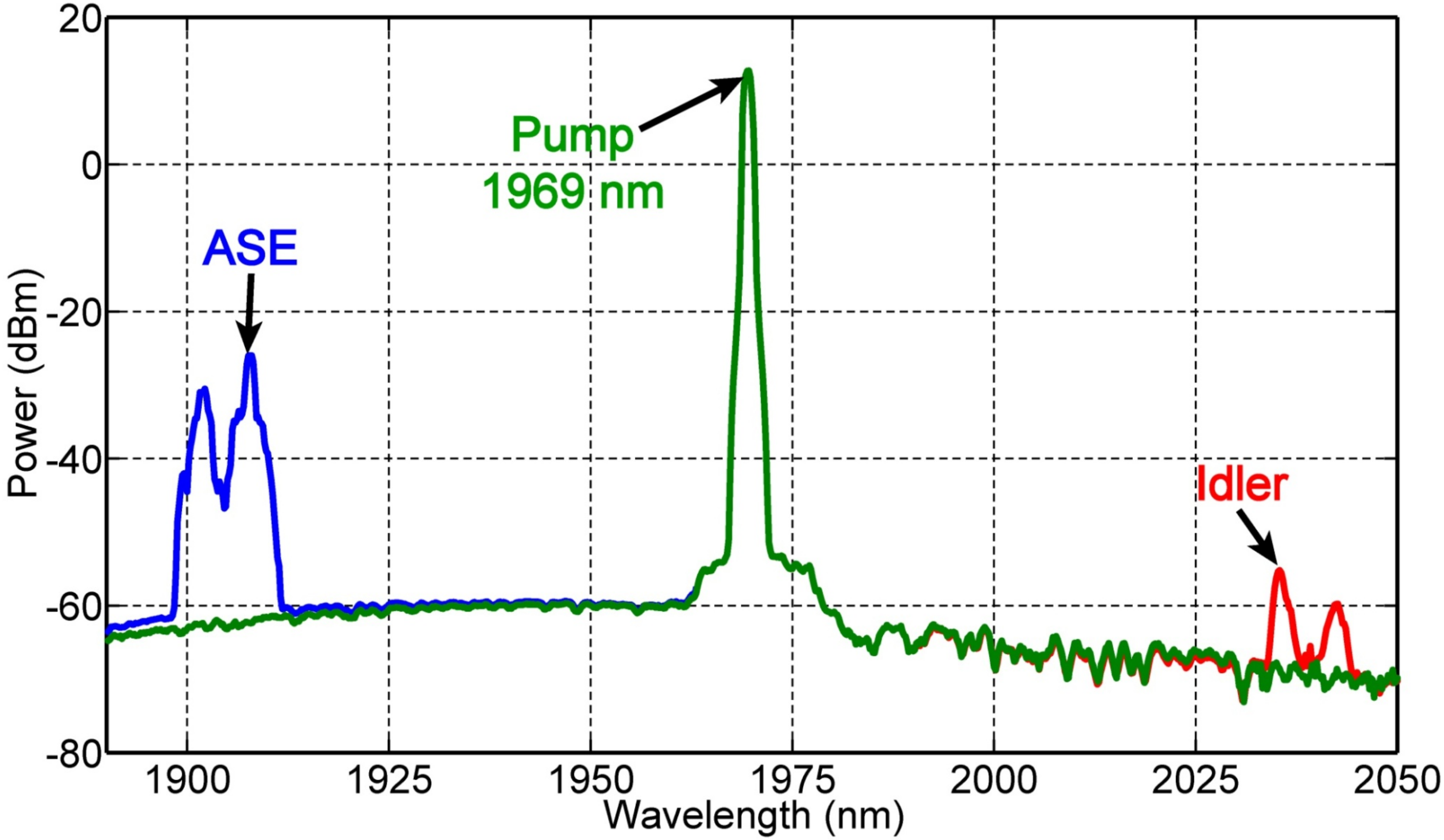
[4]*Current address: OFS Labs, 19 Schoolhouse Road, Somerset, New Jersey 08873, USA*

**Corresponding author: wgreen@us.ibm.com*

(b)

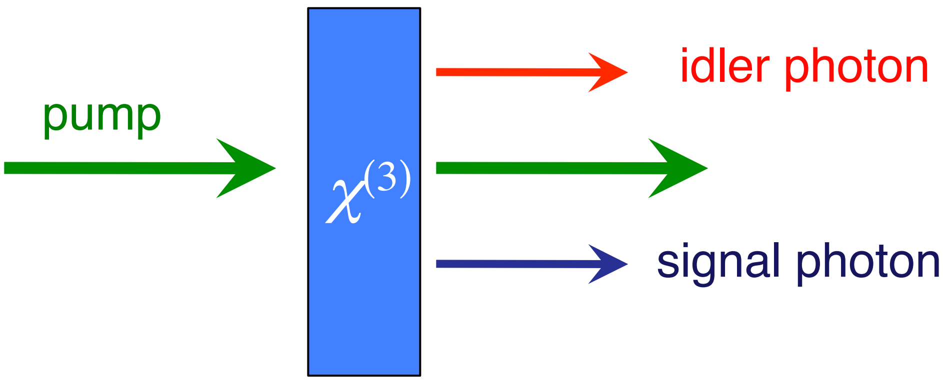


Frequency Conversion of Incoherent Source

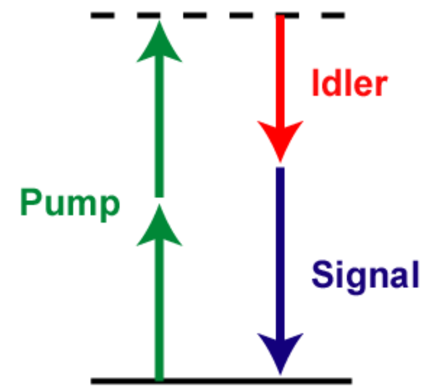


- 50-mW pump at 1969 nm, ASE from thulium fiber amplifier

Application: Generation of Correlated Photons via Four-Wave Mixing



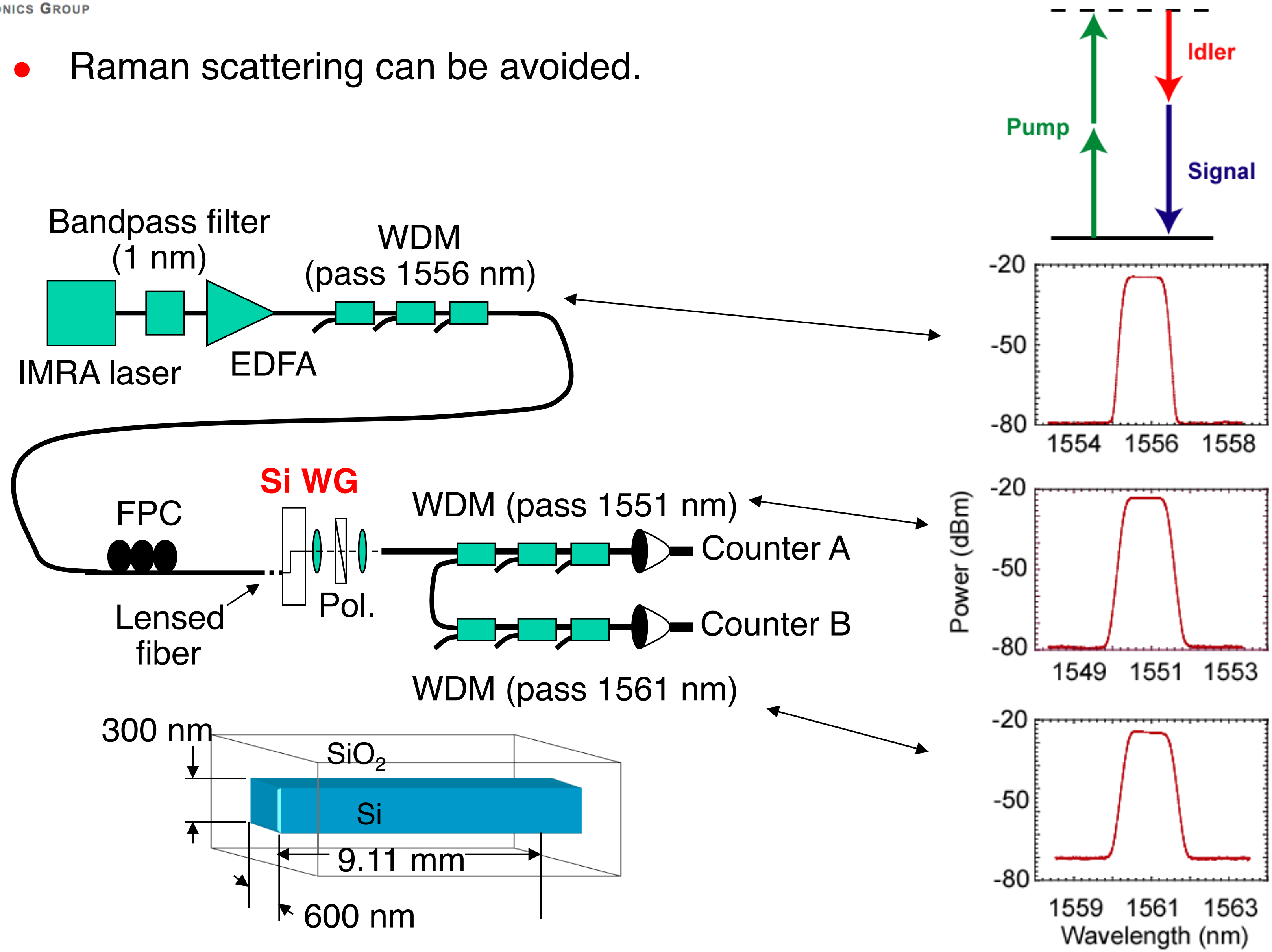
nonlinear medium



energy conservation

Application: Chip-Based Source for Correlated Photons

- Raman scattering can be avoided.



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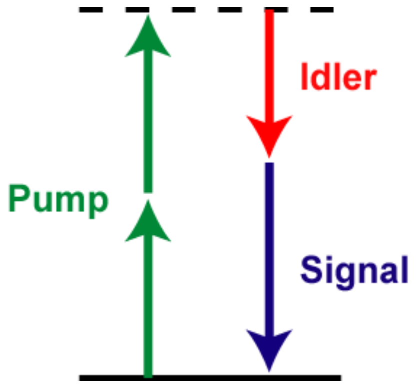
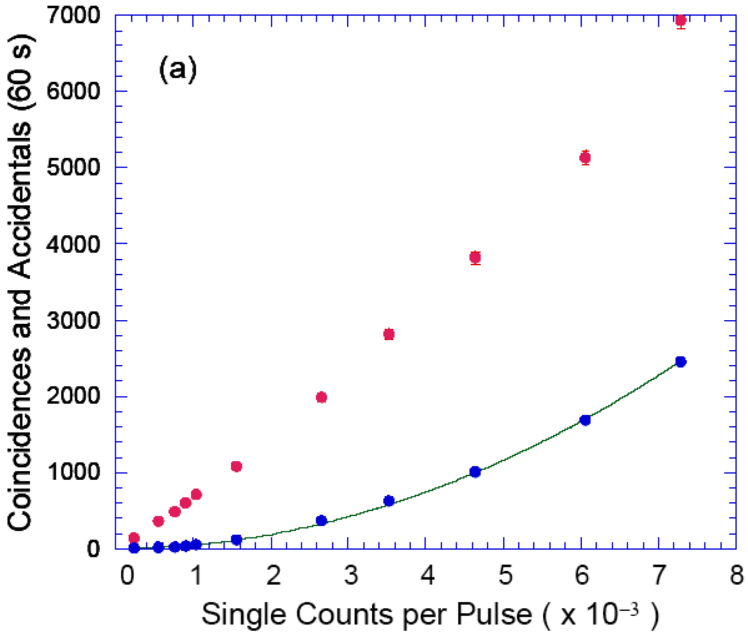
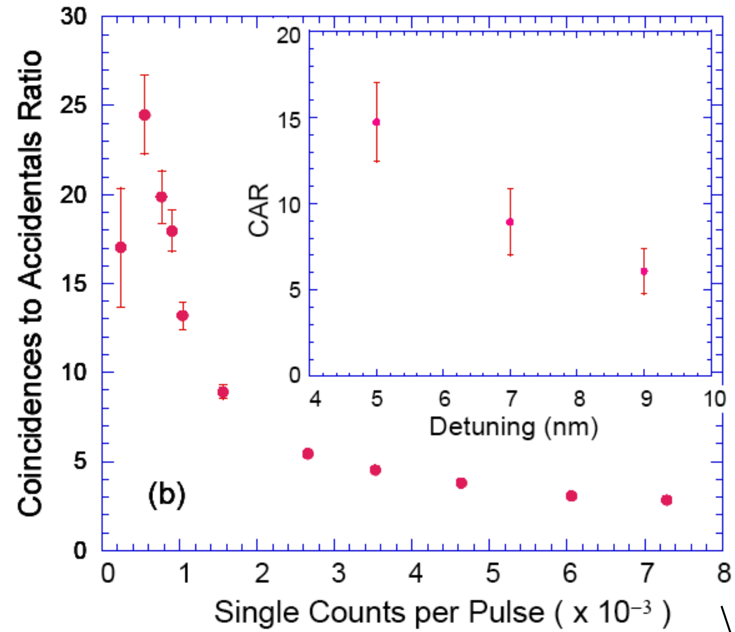
Generation of Correlated Photons in Si

Columbia University



- Results show good quantum characteristics.
- Raman scattering can be avoided.





10^9 W/cm^2

Sharping, Lee, Foster, Turner, Lipson, Gaeta, and Kumar, *Opt. Express* **14**, 12388 (2007),

Contribution of Free-Carriers Spoils Correlations

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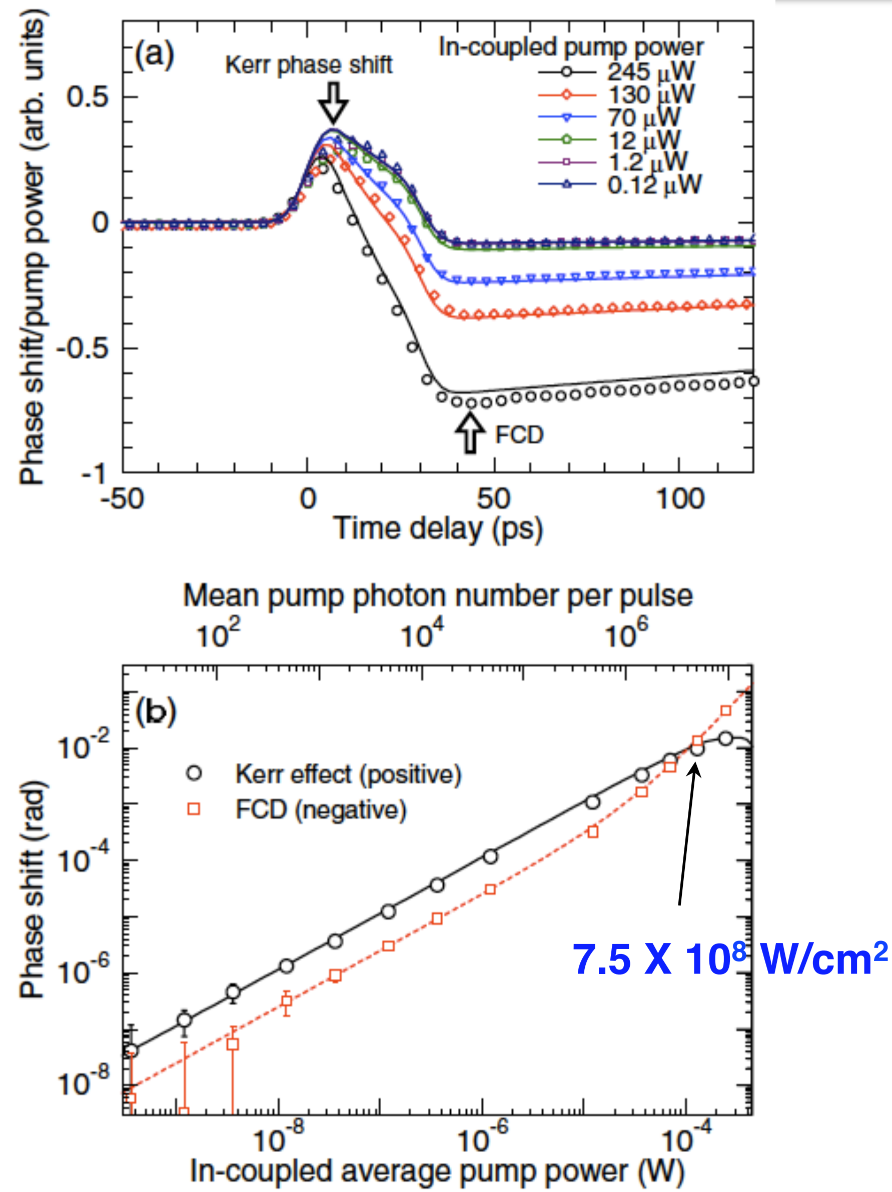
Columbia University

- Plasma dispersion effect leads to generation of blue photons.

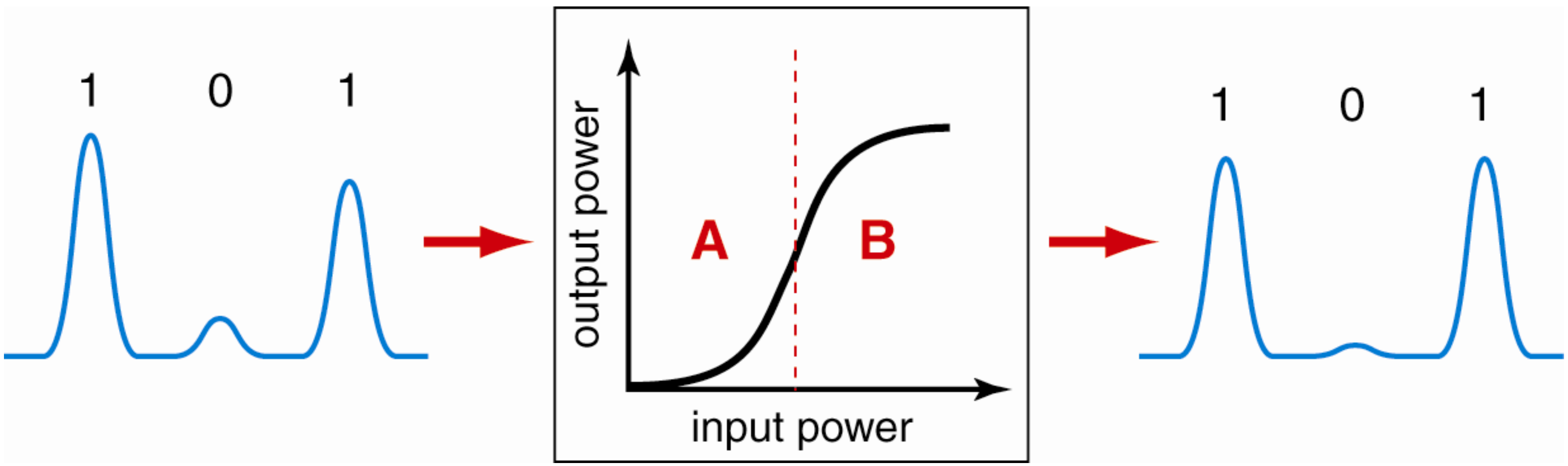
- $\chi^{(3)}$ due to free-carriers comparable to electronic for peak intensities ~ 7.5 X 10^8 W/cm^2



Matsuda, *et al.*, Appl. Phys. Lett. **95**, 171110 (2009).

Application: Signal Regeneration & Reshaping

S-shaped power transfer function



- **Region A**
  - Reduces fluctuations on the logical 0's.
  - Improves the extinction ratio.
- **Region B**
  - Reduces fluctuations on the logical 1's.

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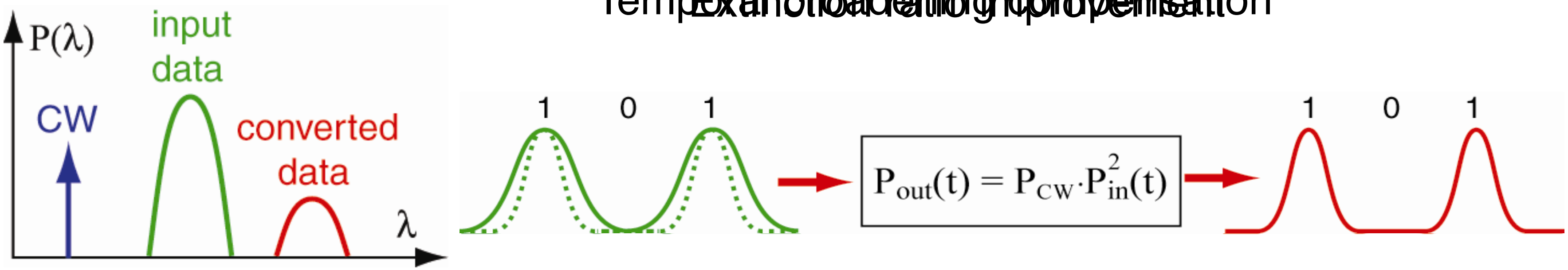
Application: FWM-Based Signal Regeneration for Optical Communications

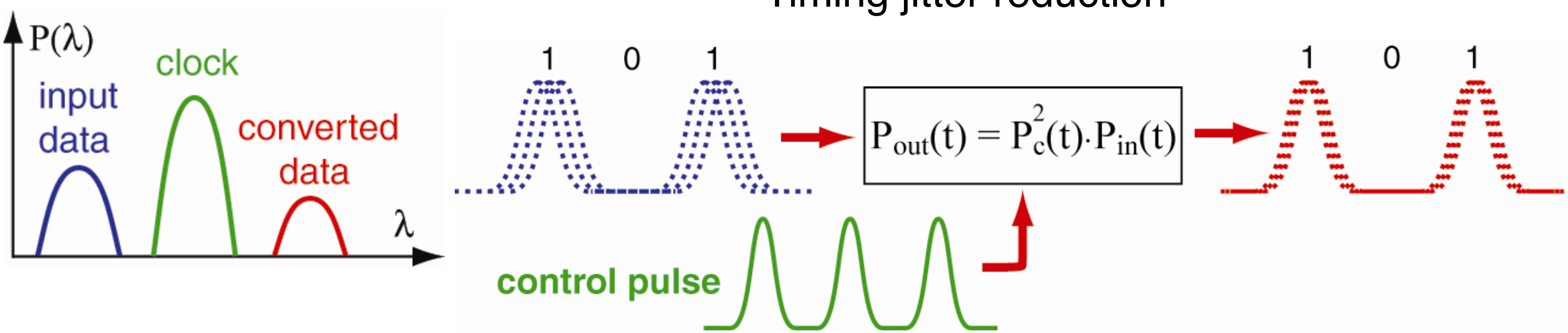
COLUMBIA UNIVERSITY

Temporal broadening compensation / Extinction ratio improvement



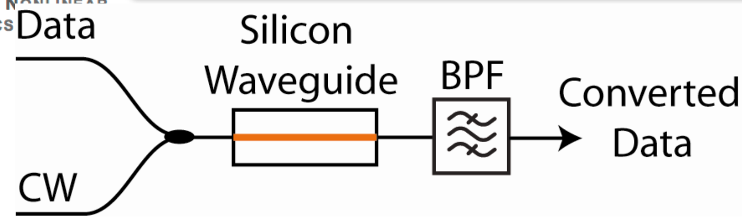
- ER improvement by FWM in fiber, Ciaramella et. al. (2001) & Bogris et al. (2003)
- ER improvement by FWM in SOA, Gosset et al. (2001) & Simos et al. (2004)

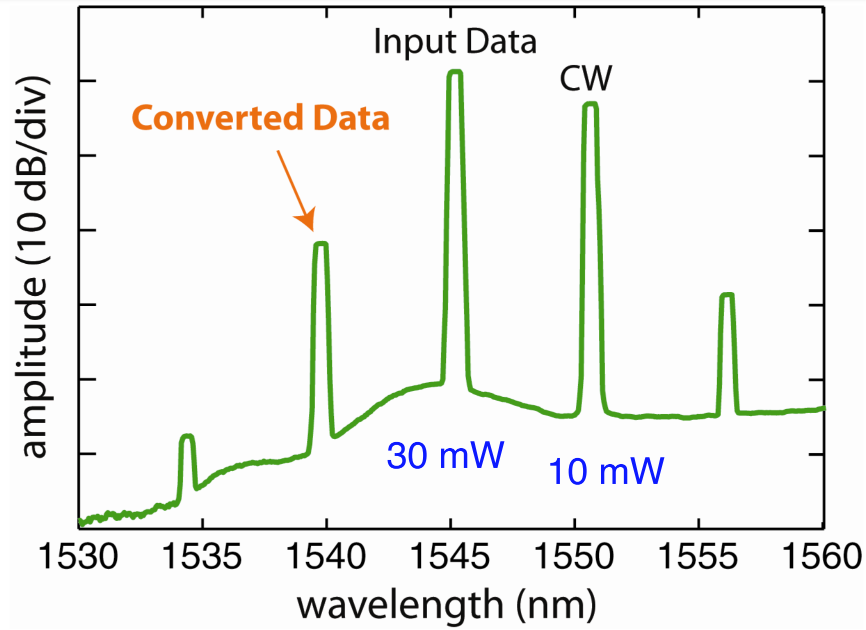
Timing jitter reduction



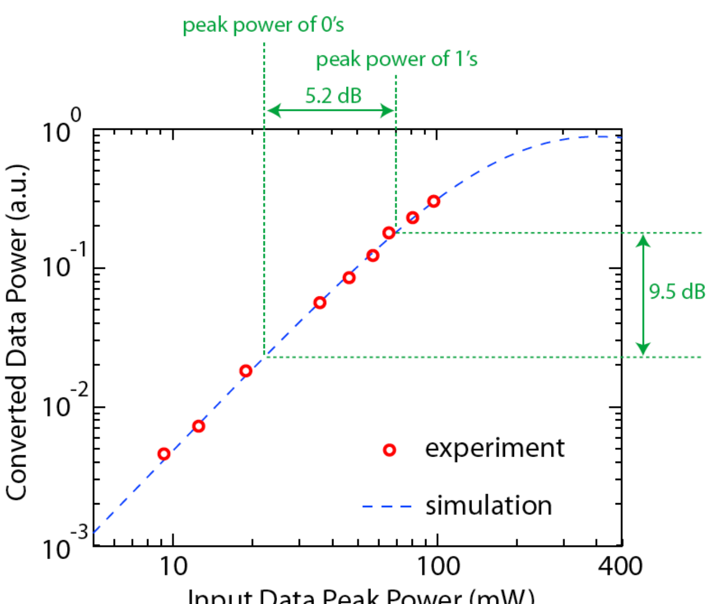
- 3R regeneration by FWM in fiber, Su et al. (2001)
- 3R regeneration by OPA in fiber, Yu et al. (2005)

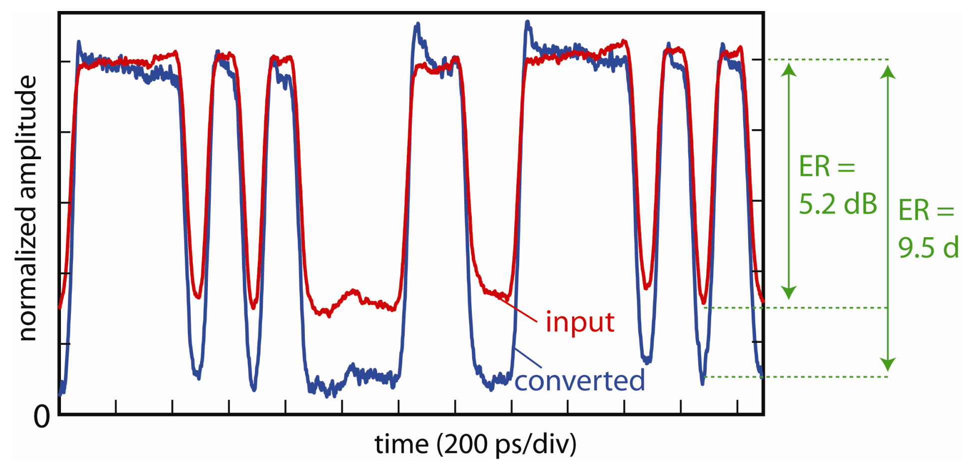
Signal Regeneration Using FWM in Si





- Data extinction ratio (ER) improved due to the quadratic input/output power transfer function.





Salem, Foster, Turner, Geraghty, Lipson, and Gaeta, *Nature Phot.* **2, 35** (2007).

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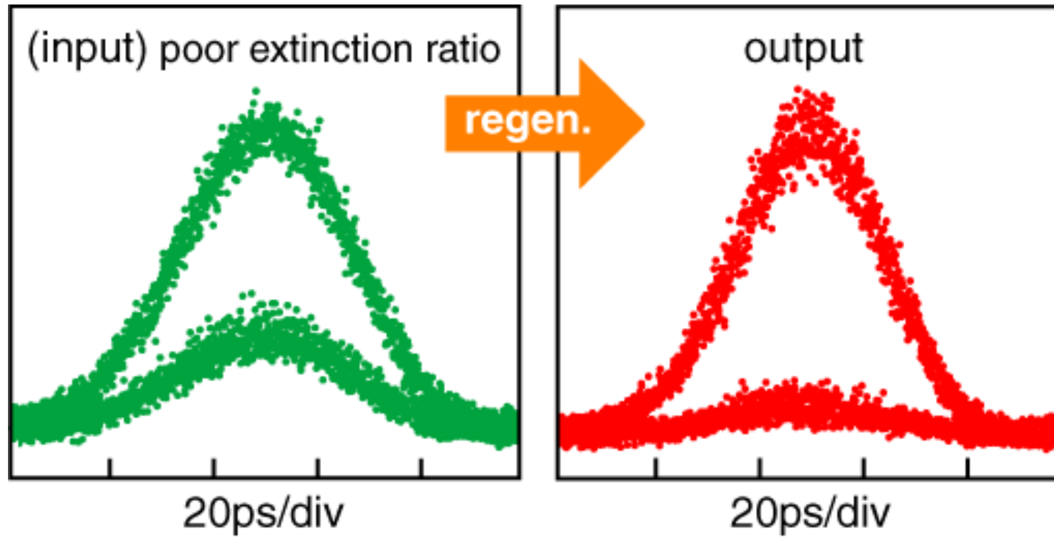
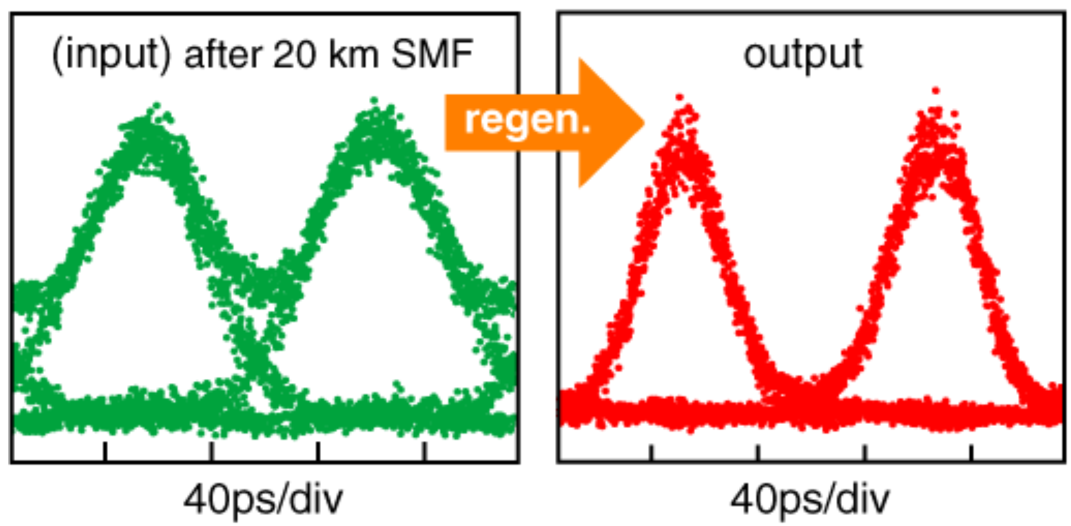
10 Gb/s RZ Data Regeneration

COLUMBIA UNIVERSITY

Extinction ratio improvement

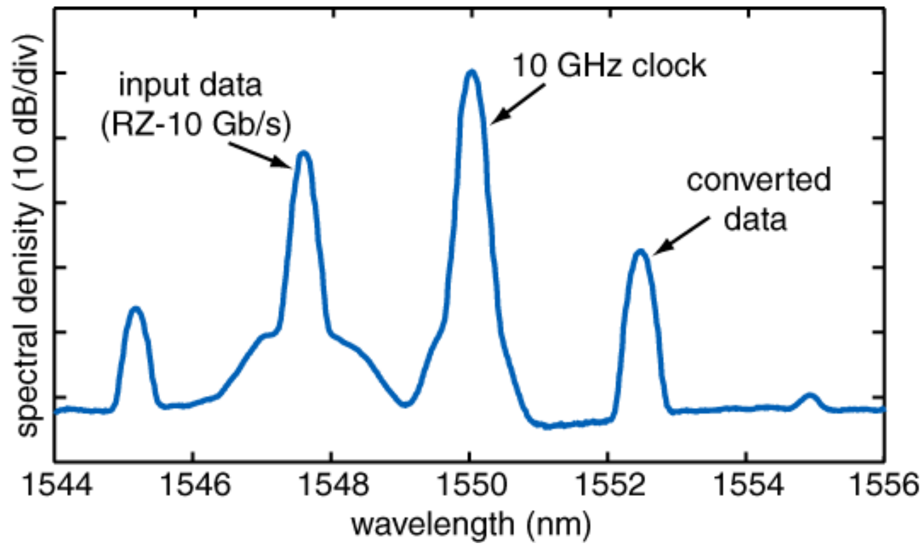


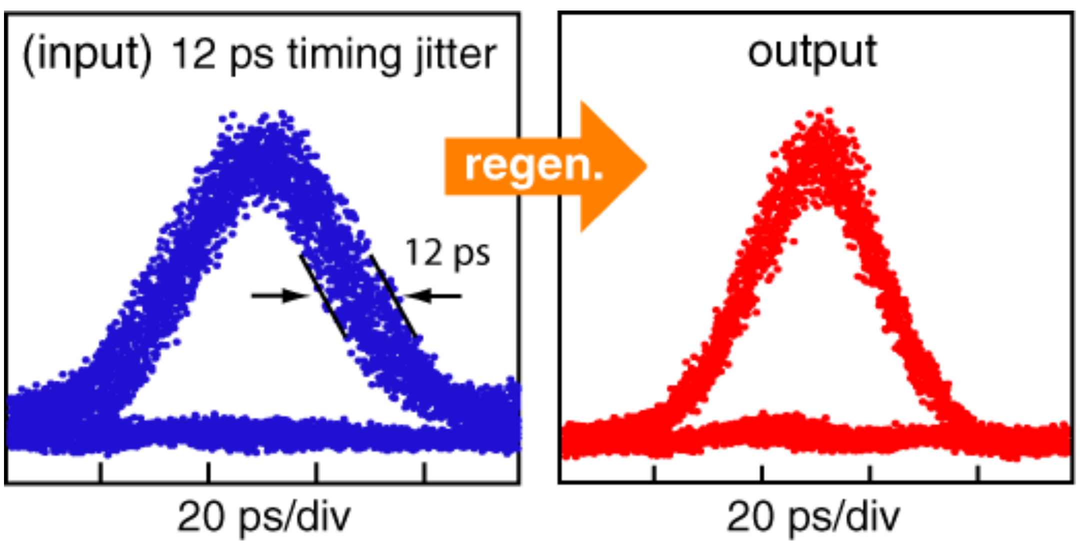
Pulse compression



10 Gb/s RZ Data Regeneration

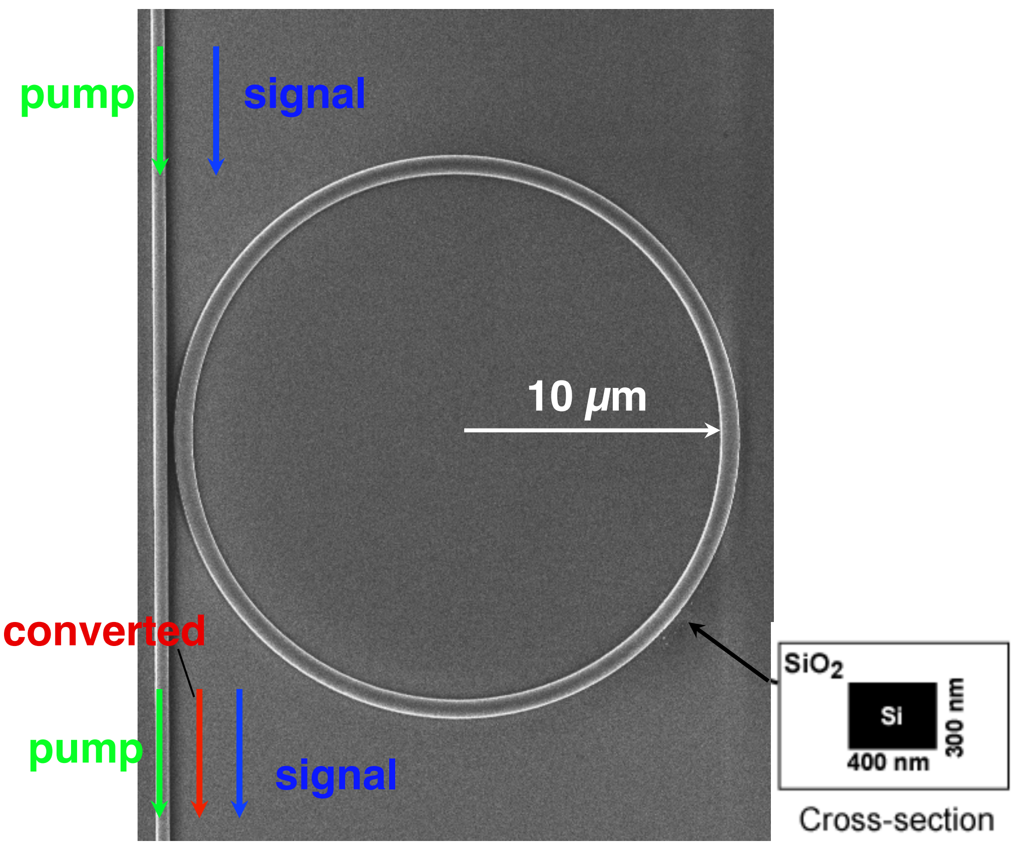
Timing jitter suppression using a clock (control) signal

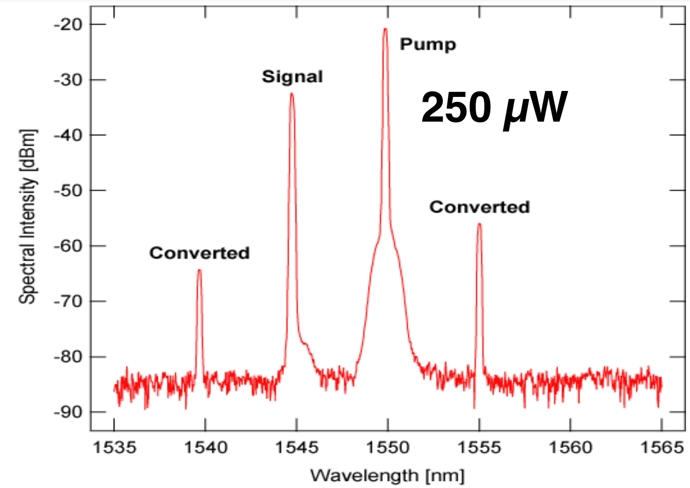


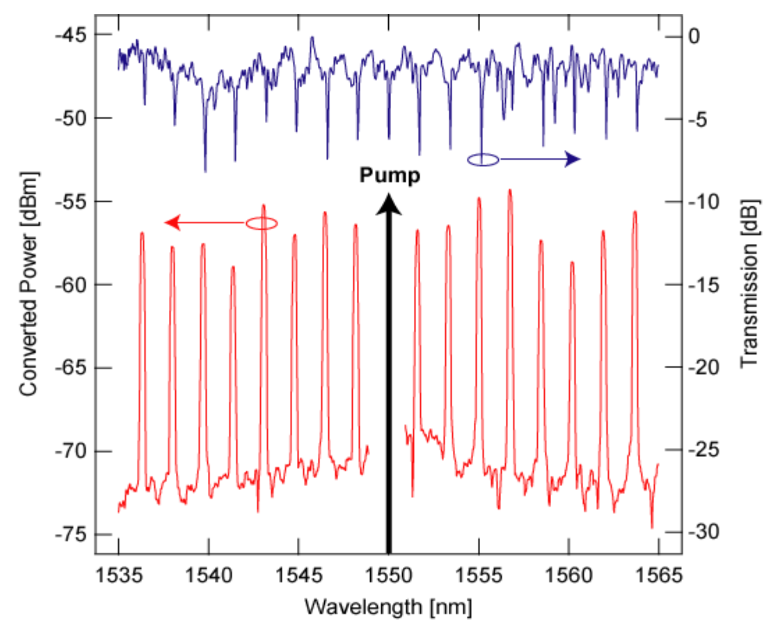


Ultralow Power Frequency Conversion

- Use ring resonator to enhance efficiency of FWM.
- Frequency conversion: < **mW** cw powers.







Turner, Foster, Gaeta, and Lipson, *Opt. Express* (2008).